

Spin-orbit torque in magnetic heterostructures: spin filtering detection of antiferromagnetic resonance and ultrasensitive Sagnac Kerr interferometry

Yunqiu Kelly Luo

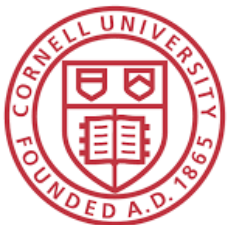
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University of Southern California



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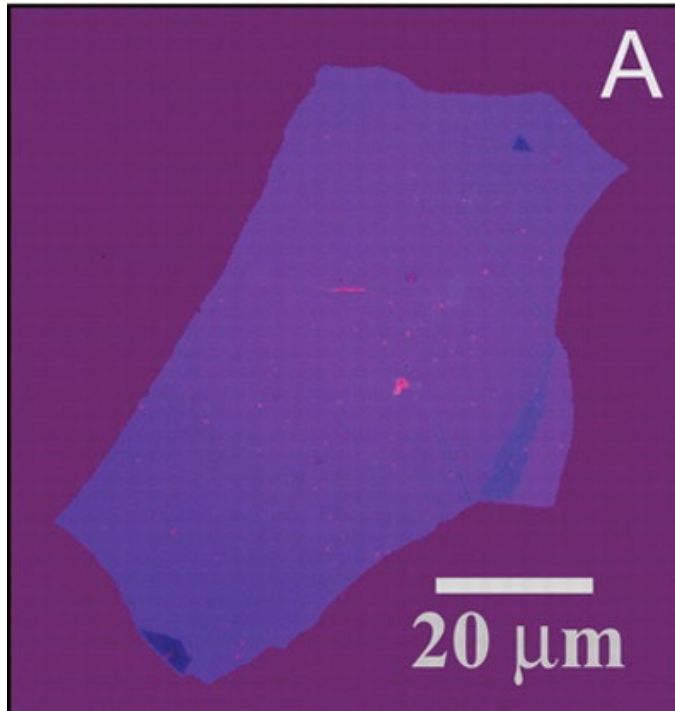
Ultrafast Quantum Opto-Spintronics Group at USC:

<https://sites.usc.edu/kellyluolab/>



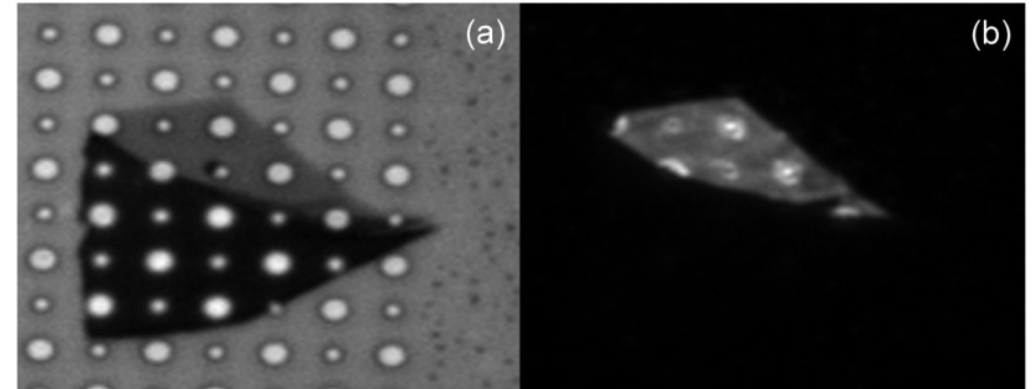
The zoo of 2D van der Waals materials

2004: Graphene



Novoselov, Kostya S., et al. "Electric field effect in atomically thin carbon films." *science* 306.5696 (2004): 666-669.

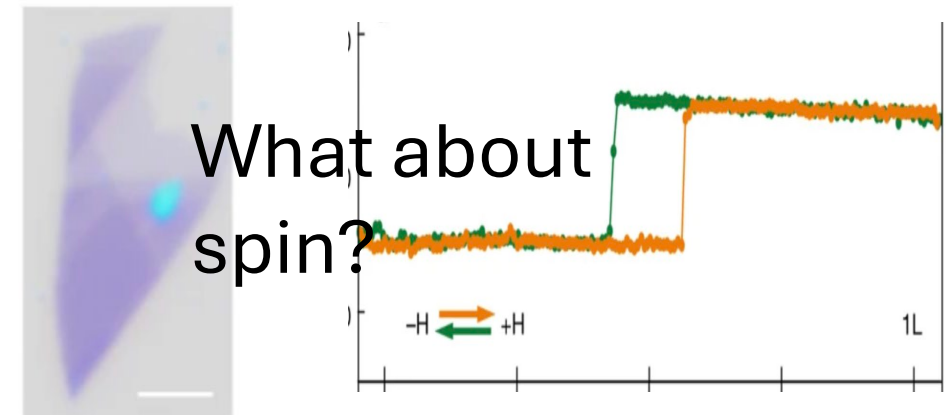
2010: TMDs (Transition Metal Dichalcogenides)



Splendiani, Andrea, et al. "Emerging photoluminescence in monolayer MoS₂." *Nano letters* 10.4 (2010): 1271-1275.

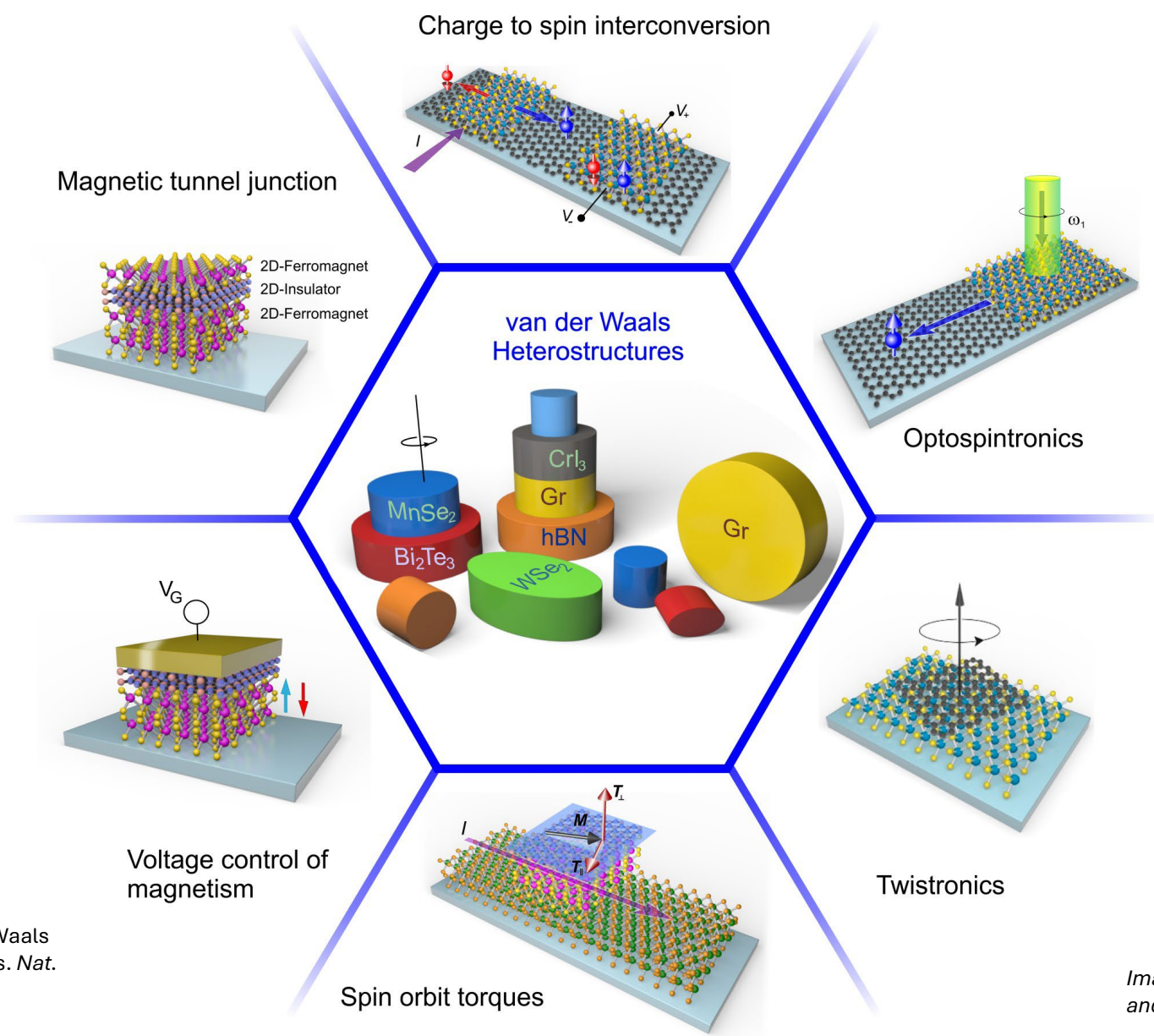
Mak, Kin Fai, et al. "Atomically thin MoS₂ : a new direct-gap semiconductor." *Physical review letters* 105.13 (2010): 136805.

2017: Magnets



Huang, Bevin, et al. "Layer-dependent ferromagnetism in a van der Waals crystal down to the monolayer limit." *Nature* 546.7657 (2017): 270-273.

2D magnetic heterostructures for exploring new interfacial phenomena and technologies



Sierra, J.F., Fabian, J., Kawakami, R.K. et al. Van der Waals heterostructures for spintronics and opto-spintronics. *Nat. Nanotechnol.* **16**, 856–868 (2021).
<https://doi.org/10.1038/s41565-021-00936-x>

Ultrafast Quantum Opto-Spintronics Lab at the University of Southern California

Two Helium-free scanning optical microscope with superconducting vector magnets:

- 1) Attodry 2100: 9-1-1 T
- 2) Cryomagnetics Vari-6-1-1 T

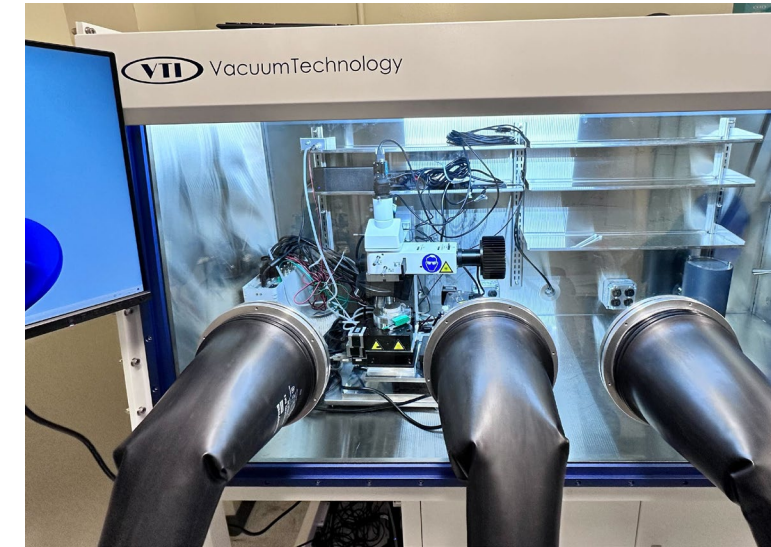
Ultrafast lasers (visible to mid-IR):

- 1) Ti:sapphire OPO
- 2) Crogenic Sagnac Kerr scanning interferometry

- **Glovebox** to be connected with **UHV suitcase** for air-free interface with beamline work.

- **HQ graphene automatic transfer stage.**

We are recruiting! <https://sites.usc.edu/kellyluolab/>



USC CORE NANOFABRICATION FACILITIES
Viterbi School of Engineering

National and International User Facilities:

NSF National Extreme Ultrafast Science Facility (NeXUS) at Ohio State:

What's the dynamic processes of electron and spin correlations?

➤ **Time-resolved angle-resolved photoelectron spectroscopy (tr-ARPES):**

1 kW laser, attosecond and femtosecond pulse, up to 100 eV, spectral resolution < 30 meV

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<https://sites.usc.edu/kellyluolab/>



Bessy II Synchrotron MAgnetic X-raY Microscope with UHV Spectroscopy (MAXYMUS):

What's the information processing speed in the atomically thin magnets?

➤ **Time-resolved scanning transmission X-ray microscope (tr-STXM):**

captures element-specific magnetization dynamics with femtosecond time resolution.



Molecular Foundry - Lawrence Berkeley National Lab:

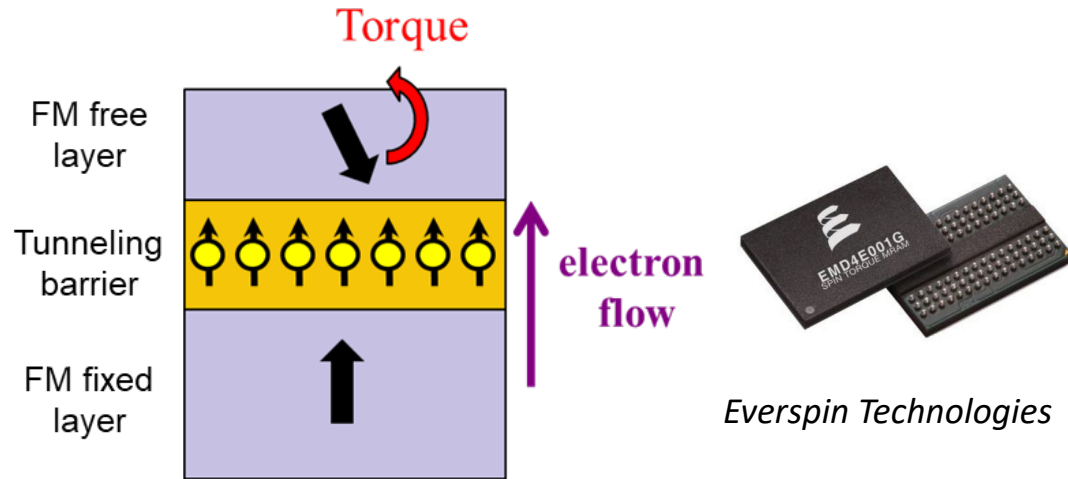
What's the nanoscale surface spin texture?

➤ **Spin-Polarized Low-Energy Electron Microscope (qSPLEEM):**

spin-resolved magnetic imaging of the unoccupied state down to 20 nm.



Manipulating magnetic materials using electron spins

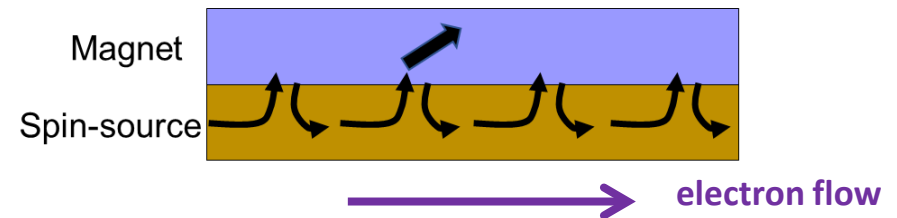


Spin Transfer Torque

- Existing MRAM technology: Major silicon foundries offer as a standard option for embedded applications in 2018-19.
- Fundamental maximum efficiency is 1 unit of $\hbar/2$ per unit of charge in current

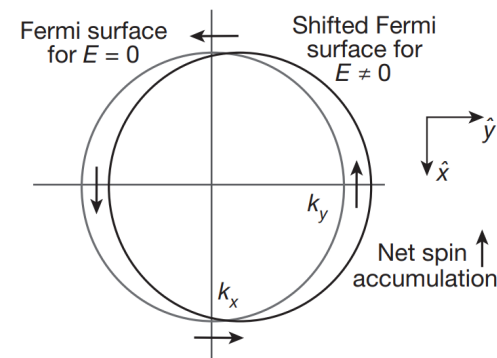
Spin-orbit Torque:

- Use a non-magnetic material to generate spin current
- Efficiency no longer limited to $\hbar/2e$

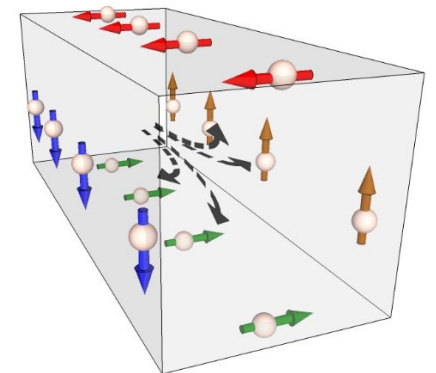


- “Spin-source” is typically a material with large spin-orbit coupling

Spin-momentum locking in topological surface states



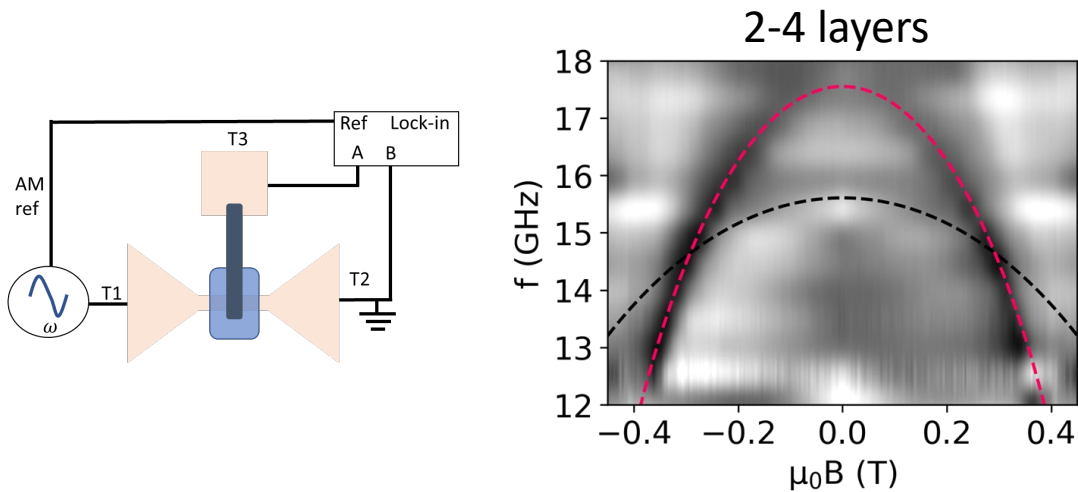
Bulk spin Hall effect



Mellnik, Ralph *et al.* Nature (2014)
Fan, Tserkovnyak, Wang *et al.* Nature Mater. (2014)

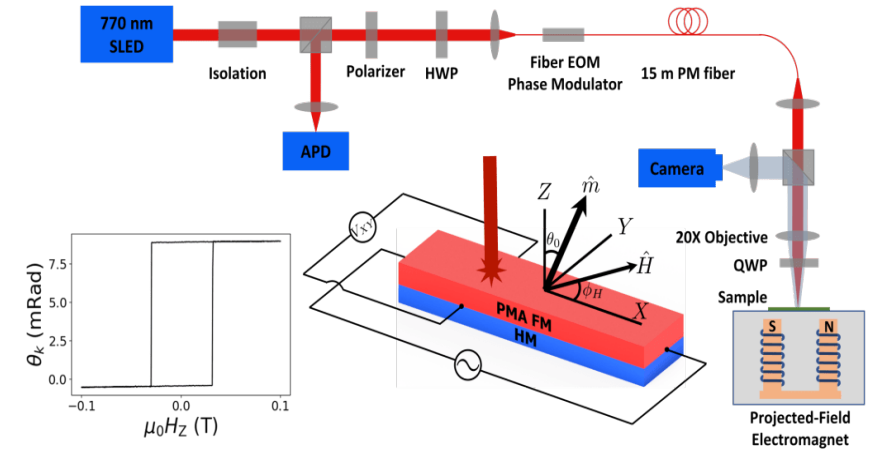
Outline

Electrical detection of antiferromagnetic resonance with electrically-tunable damping



Nano Letters, 22(16), 6716-6723 (2022);
Advanced Materials. 2305739 (2024)
arXiv: 2407.09462. *Science* (2025).
DOI: 10.1126/science.adq8590

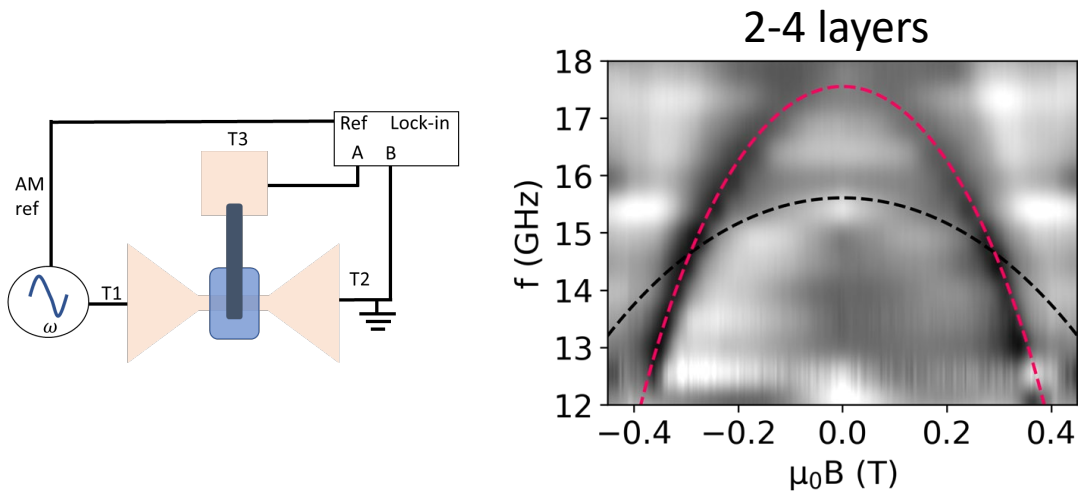
High-sensitivity optical SOT metrology: Sagnac Kerr interferometry



Science Advances 9(36), eadi9039 (2023);
First version: arXiv: 2109.13759 (2021)

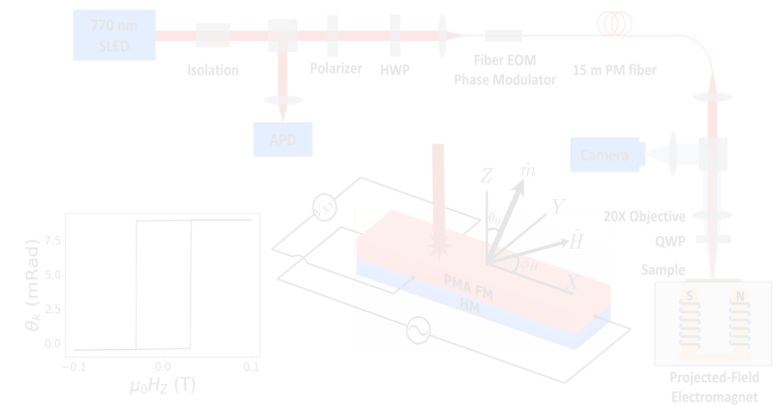
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High-sensitivity optical SOT metrology: Sagnac Kerr interferometry

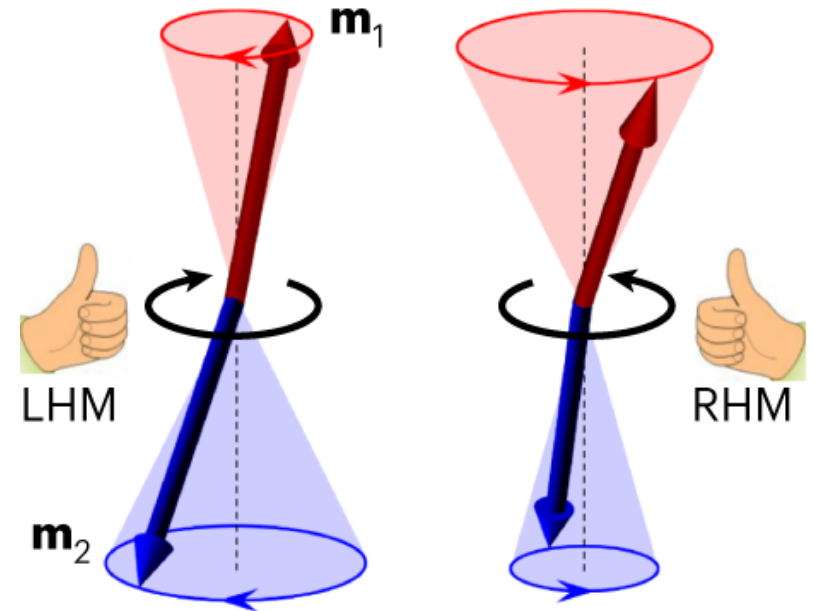


Science Advances 9(36), eadi9039 (2023);
First version: arXiv: 2109.13759 (2021)

Antiferromagnetic Spintronics: The Next Frontier

Antiferromagnets vs ferromagnets:

- 1) Zero net magnetization: Stable to perturbation from external field.
- 2) Exchange coupling between sublattices:
 - Richer variety of resonance modes and mode-mode coupling.
 - Faster dynamics over a wide range (GHz to THz).



Han, J., Cheng, R., Liu, L., Ohno, H., & Fukami, S. (2023). Coherent antiferromagnetic spintronics. *Nature Materials*, 22(6), 684-695.

Baltz, V., Manchon, A., Tsoi, M., Moriyama, T., Ono, T., & Tserkovnyak, Y. (2018). Antiferromagnetic spintronics. *Reviews of Modern Physics*, 90(1), 015005.

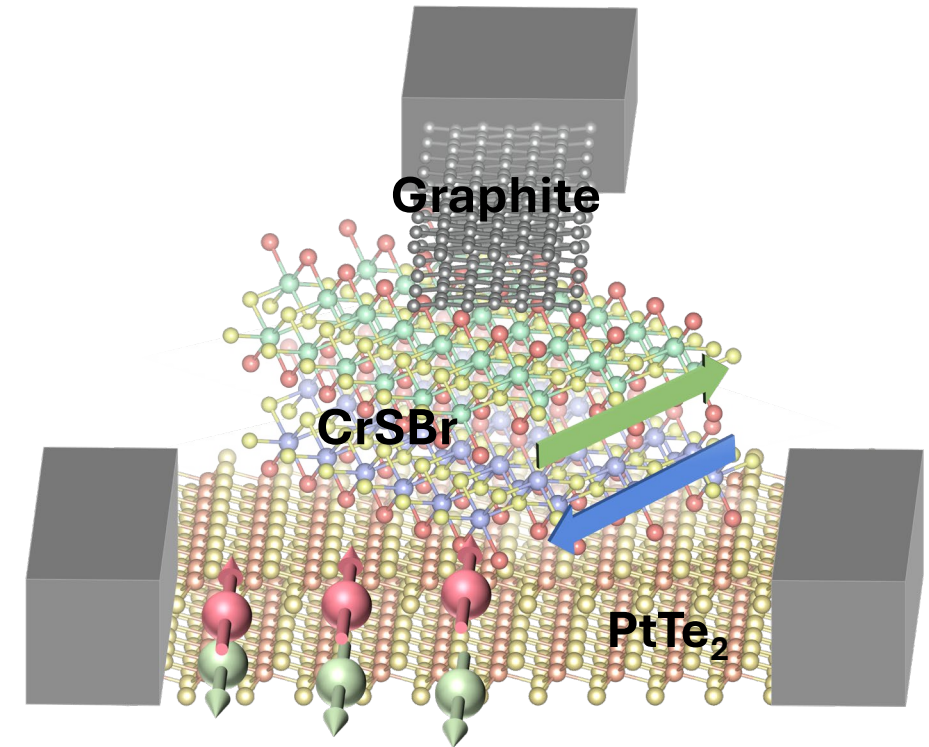
Spin-Orbit Torque Control of Antiferromagnetic Resonance (AFMR)

1

Electrical detection of
AFMR using spin-filter
tunneling resistance

2

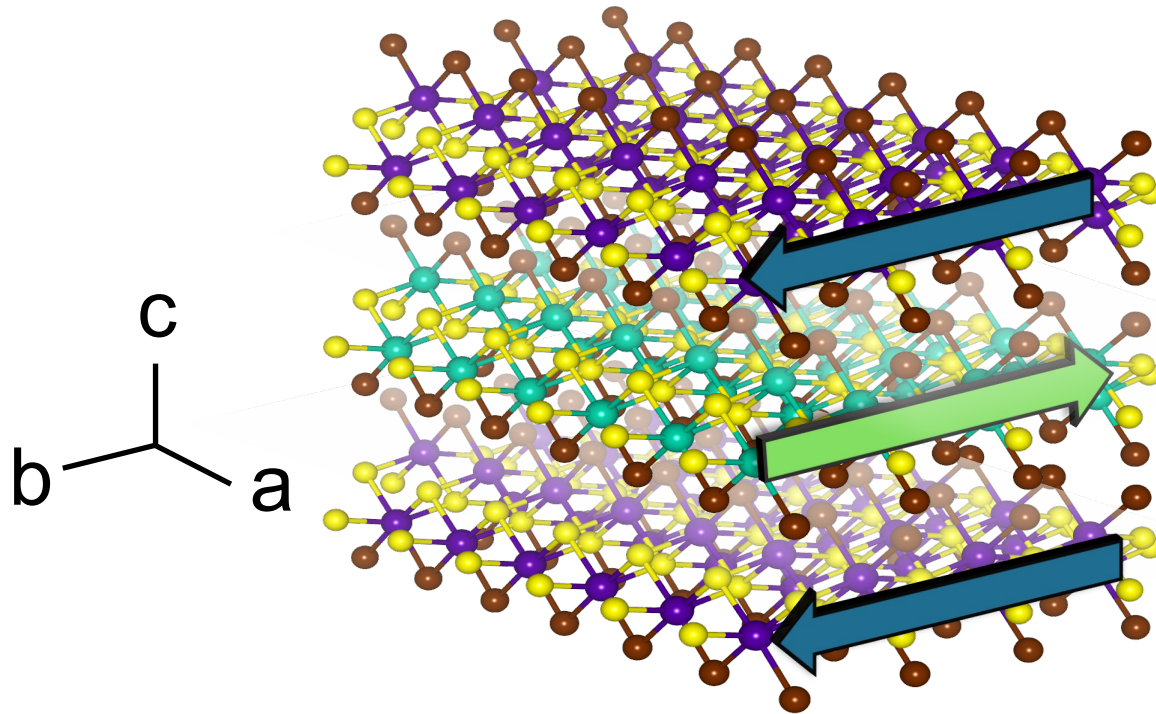
Spin-Orbit torque
Modulation of
Antiferromagnetic
Resonance



Cham, T. M. J., Huang, X., Chica, D. G., Watanabe, K., Taniguchi, T., Roy, X., Luo, Y. K., & Ralph, D. C.
“Spin-filter tunneling detection of antiferromagnetic resonance with electrically-tunable damping”
arXiv:2407.09462. Science (2025). DOI: 10.1126/science.adq8590

CrSBr: vdW antiferromagnetic semiconductor

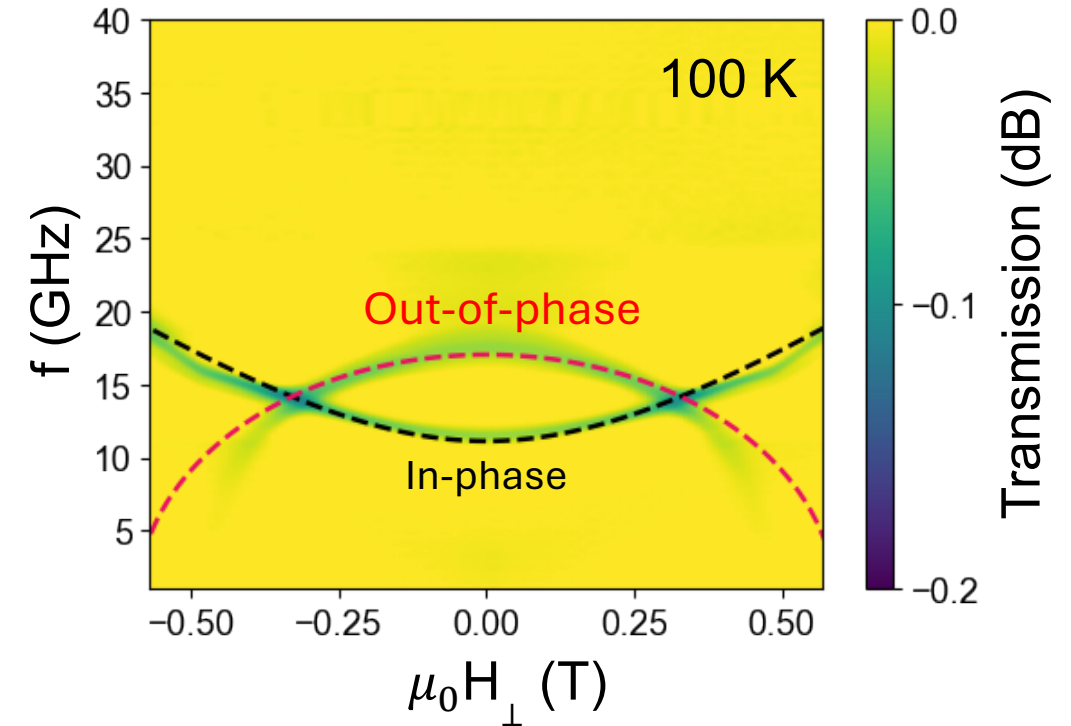
Triaxial anisotropy along a, b, c crystal axes.



Telford, E.J. et al. 2020. *Advanced Materials*, 32(37), p.2003240.

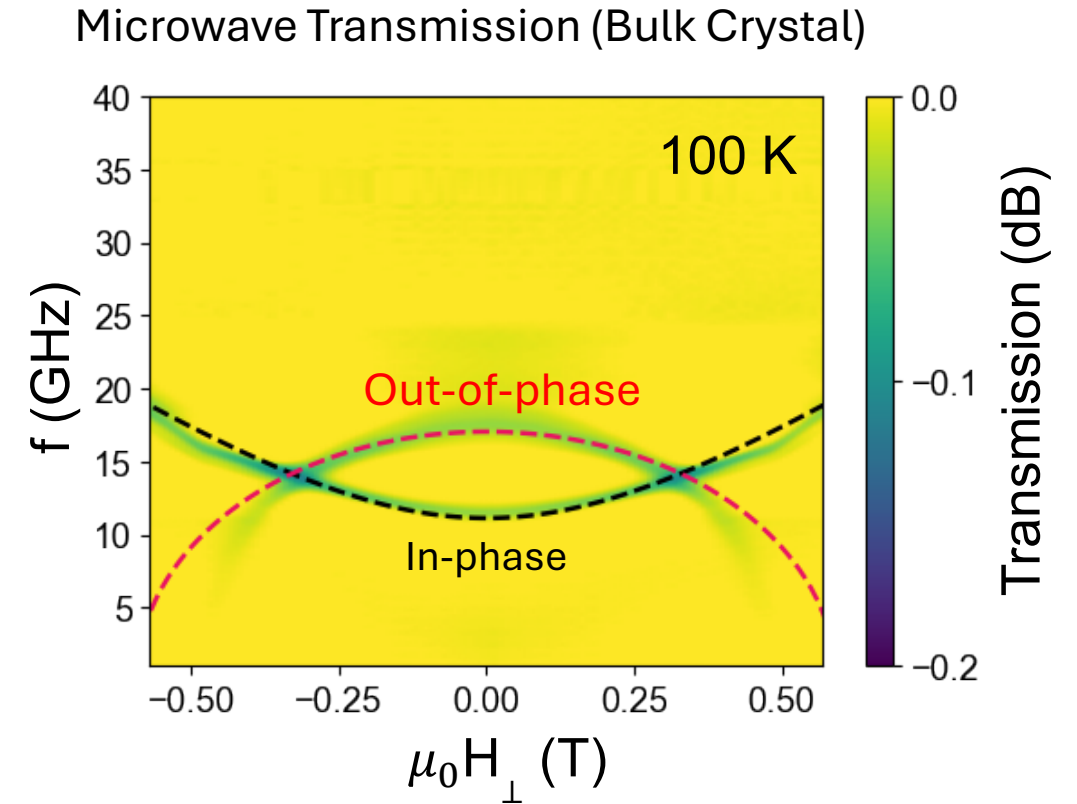
Lee, K. et al. *Nano Letters*, 21(8), pp.3511-3517.

Microwave Transmission (Bulk Crystal)



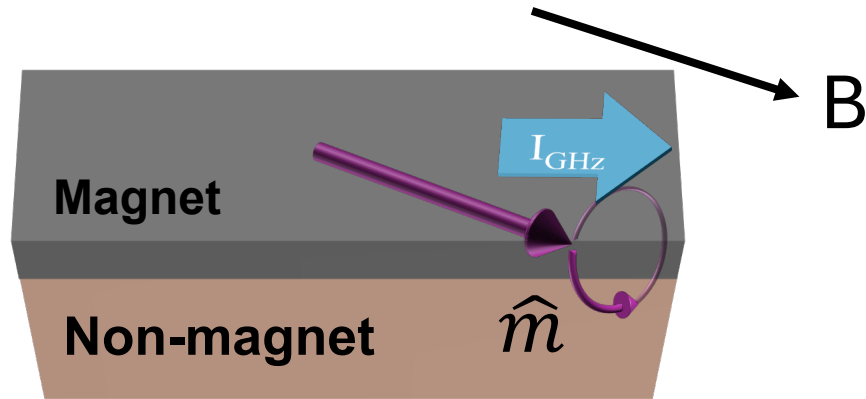
Our work: Cham, T. M. J., Ralph, D. C., & Luo, Y. K. et al. *Nano Letters* 22.16 (2022): 6716-6723.

Is it possible to detect these modes down to atomically thin layers?



Spin Torque Ferromagnetic Resonance (ST-FMR)

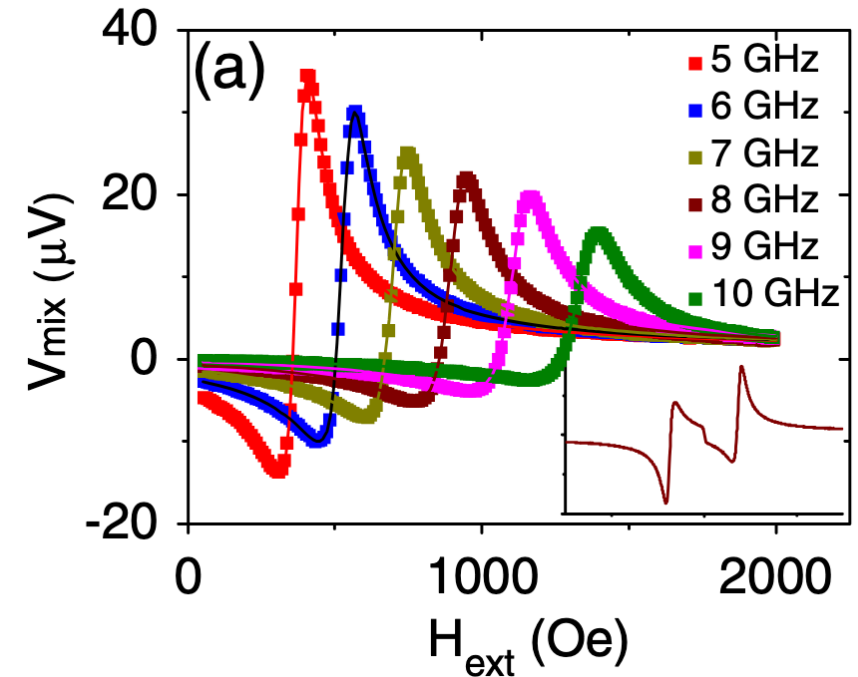
Liu, L., Moriyama, T., Ralph, D. C., & Buhrman, R. A. (2011). Spin-torque ferromagnetic resonance induced by the spin Hall effect. *Physical review letters*, 106(3), 036601.



Kittel formula: $\omega_{resonance} = \gamma \sqrt{B (B + M_{eff})}$

Rectification Voltage Readout:

$$V_{Rectified}(t) = \underbrace{I_0 \sin(\omega t)}_{\text{GHz Current}} \underbrace{(R_0 + \Delta R \sin(\omega t))}_{\text{Anisotropic Magnetoresistance}} = \frac{\Delta R I_0}{2} + O(\omega t)$$



Lorentzian components

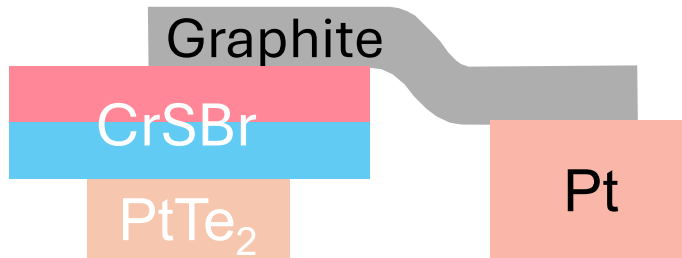
$$V_{Rectified}^{DC} \propto S \frac{\Delta^2}{\Delta^2 + (B - B_0)^2} + A \frac{B(B - B_0)\Delta}{\Delta^2 + (B - B_0)^2}$$

Spin-filter tunneling magnetoresistance of CrSBr

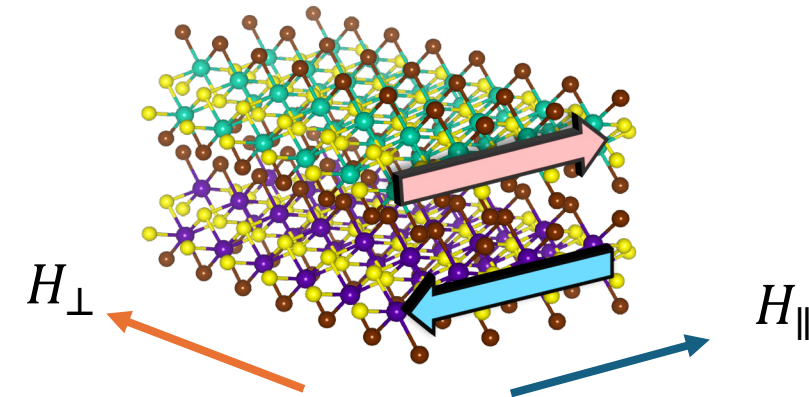
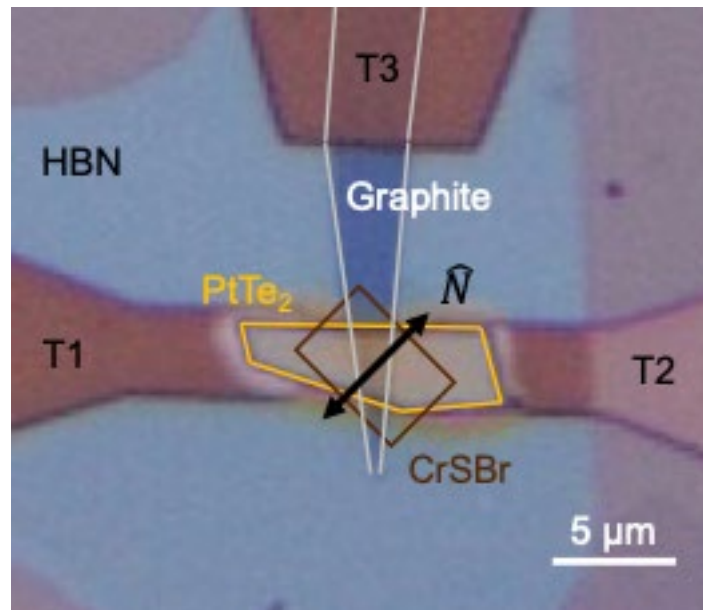
Klein, D. R. et al. *Science* 360, 1218-1222 (2018)

Song, T. et al. *Science*, 360, 1214-1218 (2018)

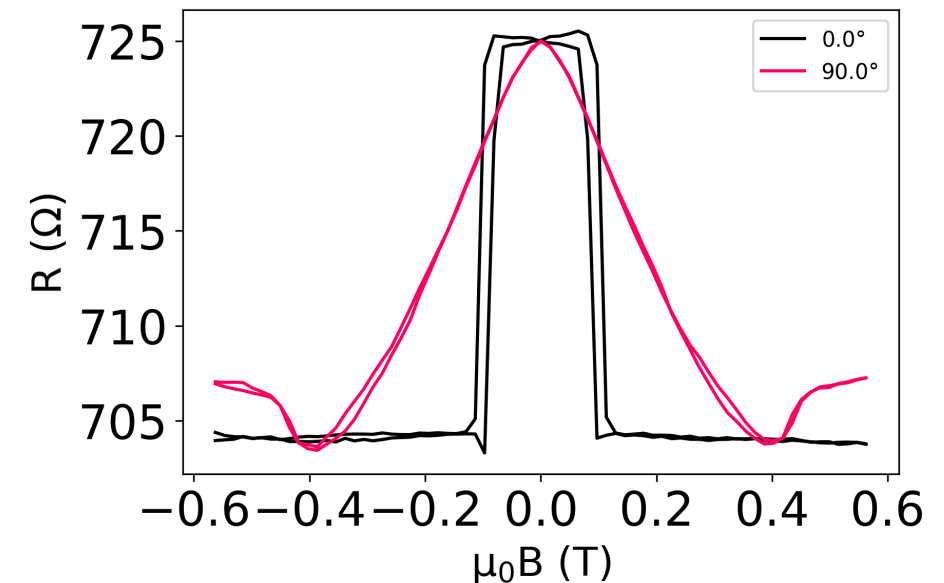
Boix-Constant et al, *Advanced Materials*, 34(41), 2204940 (2022)



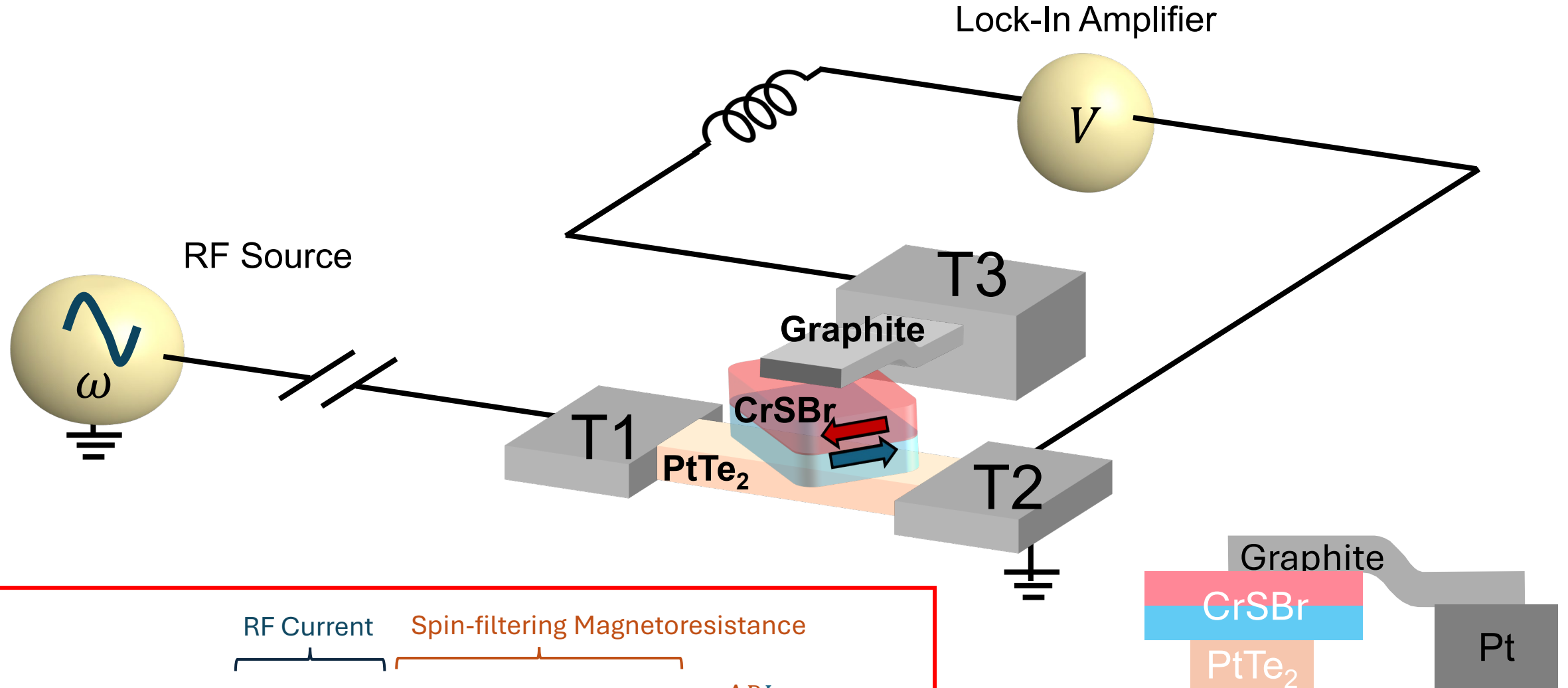
3-Terminal vdW Heterostructure Device:



Spin-filter Tunneling Magnetoresistance



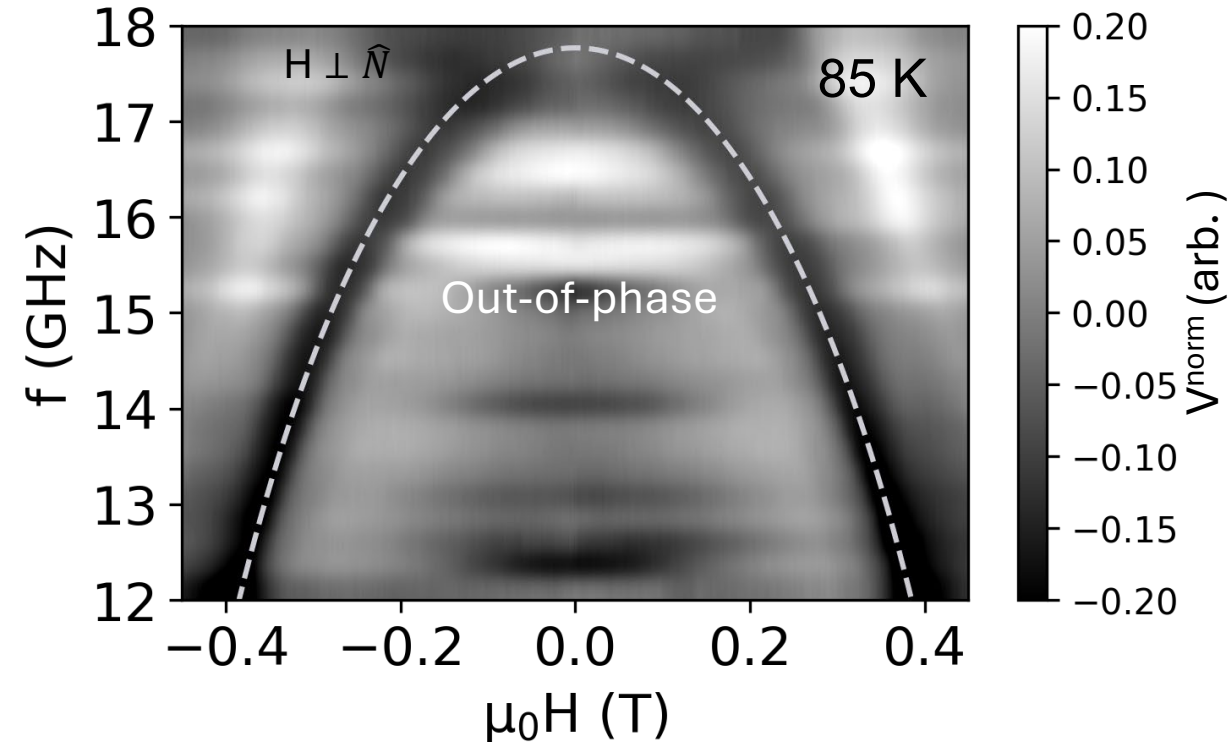
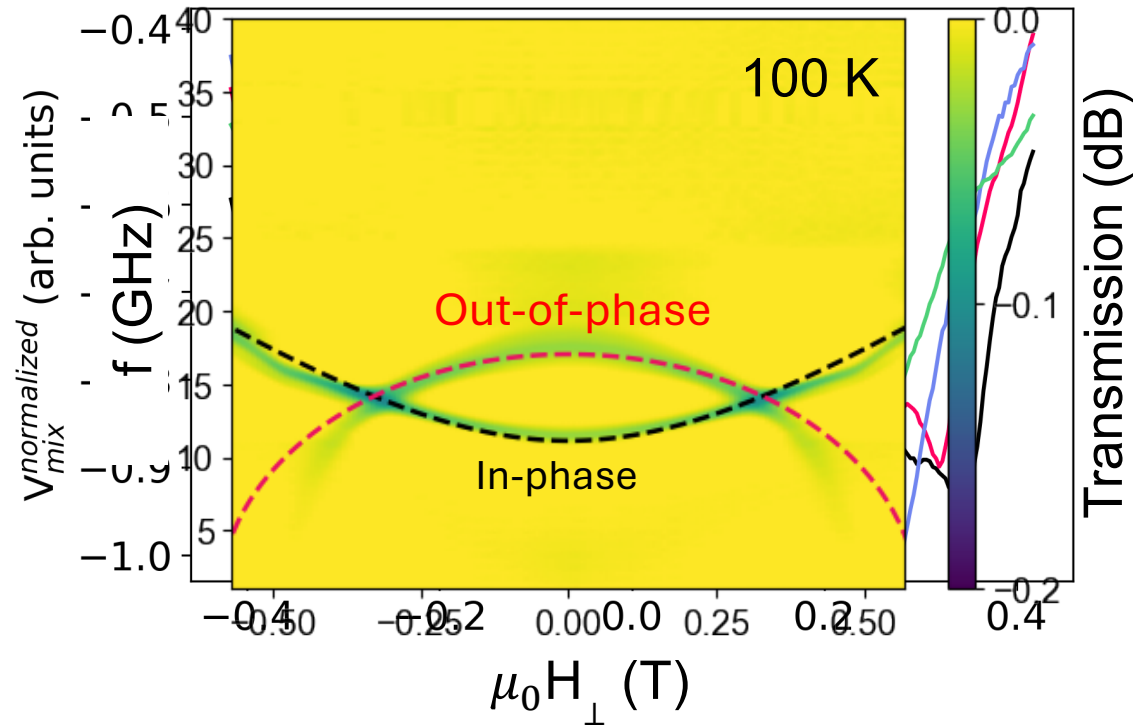
Electrical Detection of Antiferromagnetic Resonance



$$V_{Rectified}(t) = \underbrace{I_0 \sin(\omega t)}_{\text{RF Current}} \underbrace{(R_0 + \Delta R \sin(\omega t))}_{\text{Spin-filtering Magnetoresistance}} = \frac{\Delta R I_0}{2} + O(\omega t)$$

Resonance Spectrum of Bilayer CrSBr

$$V_{mix}(t) = \overbrace{I_0 \sin(\omega t)}^{\text{RF Current}} \overbrace{(R_0 + \Delta R \sin(\omega t))}^{\text{MR Response}}$$



Spin filtering tunneling junction: electrical detection of out-of-phase AFMR modes in Bilayer CrSBr

Nano Letters 22.16 (2022): 6716-6723.

arXiv:2407.09462. Science (2025). DOI: 10.1126/science.adq8590

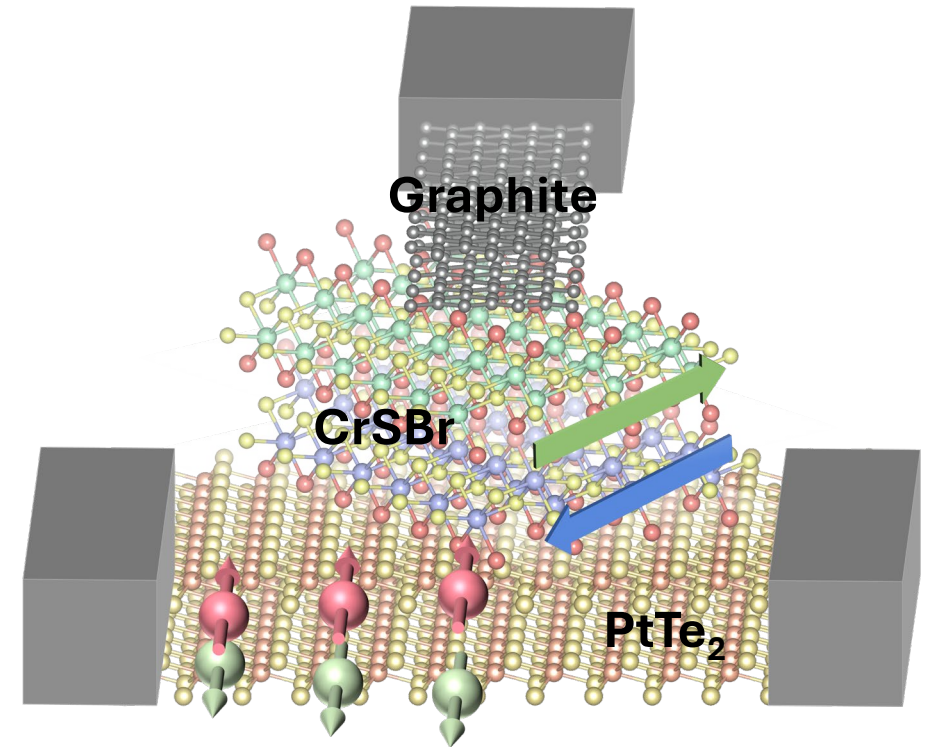
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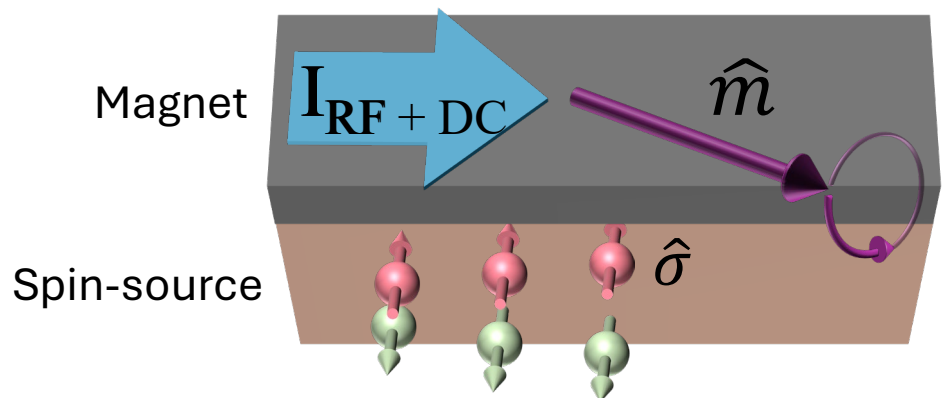
Spin-Orbit torque
Modulation of
Antiferromagnetic
Resonance



Cham, T. M. J., Huang, X., Chica, D. G., Watanabe, K., Taniguchi, T., Roy, X., Luo, Y. K., & Ralph, D. C.
“Spin-filter tunneling detection of antiferromagnetic resonance with electrically-tunable damping”
arXiv:2407.09462. Science (2025). DOI: 10.1126/science.adq8590.

Spin-torque modulation of magnetic damping

Liu, L., Moriyama, T., Ralph, D. C., & Buhrman, R. A. (2011). Spin-torque ferromagnetic resonance induced by the spin Hall effect. *Physical review letters*, 106(3), 036601.



$$\Delta \propto (\alpha + A\xi_{SH}I_{DC}\hat{\sigma} \cdot \hat{m})$$

Δ : Lorentzian linewidth

α : Gilbert damping from SOC

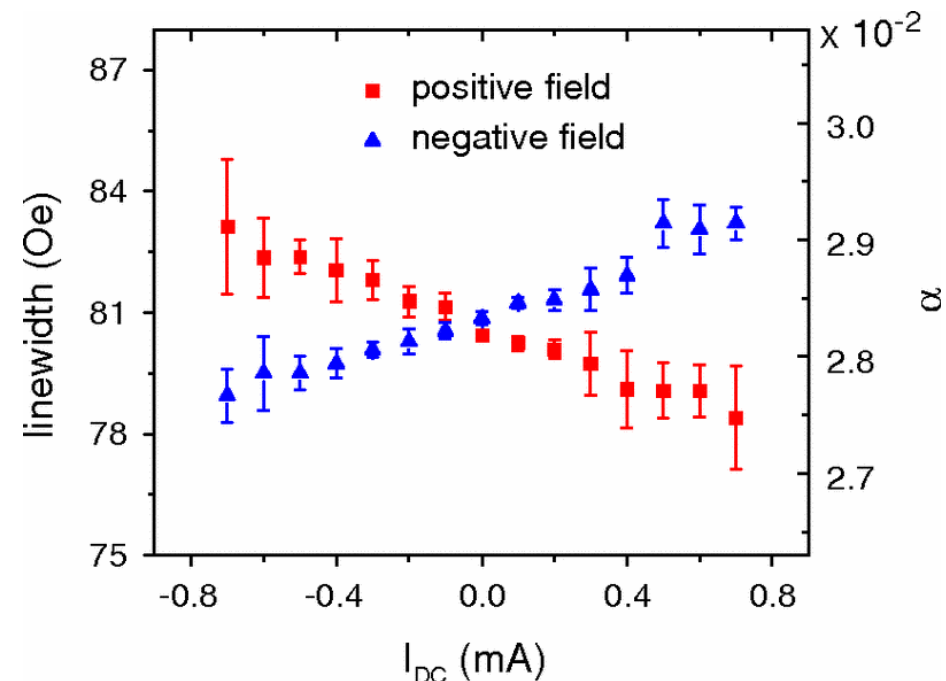
ξ_{SH} : Spin torque efficiency

I_{DC} : DC bias current

$\hat{m}$: Magnetization

$\hat{\sigma}$: Spin polarization

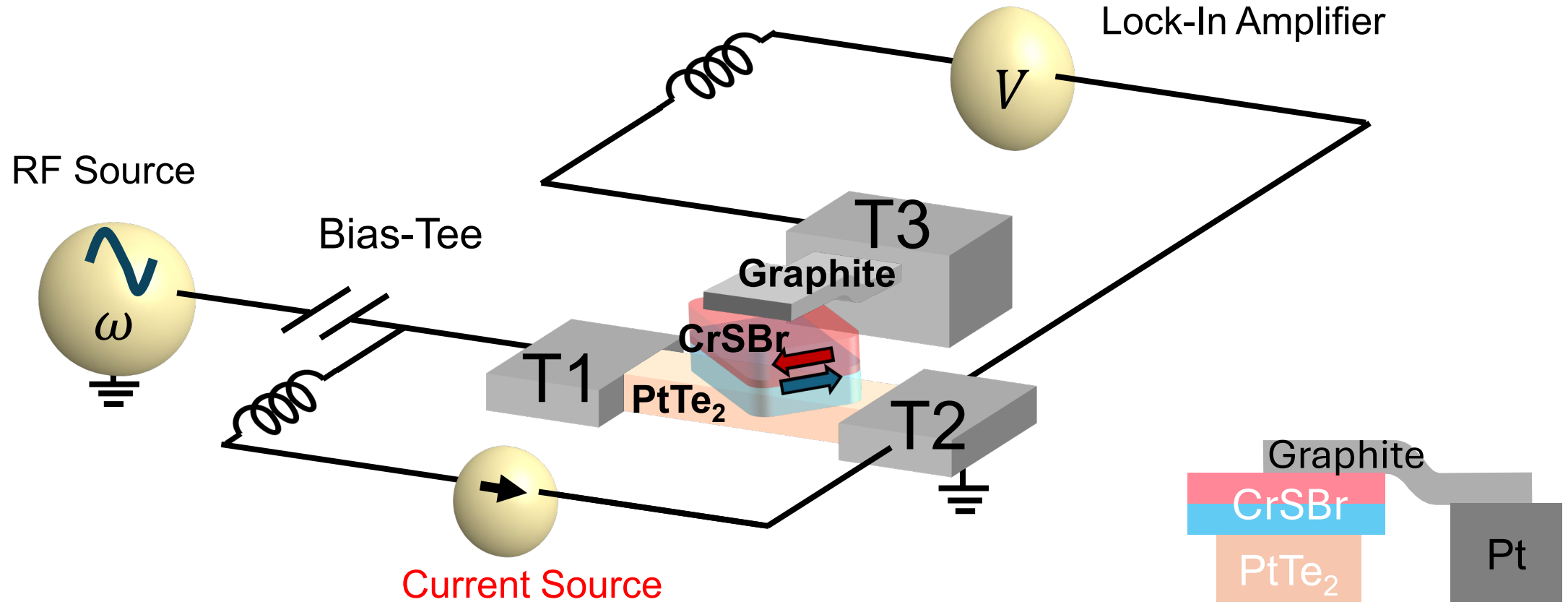
$$V_{rectified} \propto S \frac{\Delta^2}{\Delta^2 + (B - B_0)^2} + A \frac{\Delta^2}{\Delta^2 + (B - B_0)^2}$$



Modulated linewidth scales linearly with DC current, proportional to ξ_{SH}
Changes sign with $m \cdot \sigma$

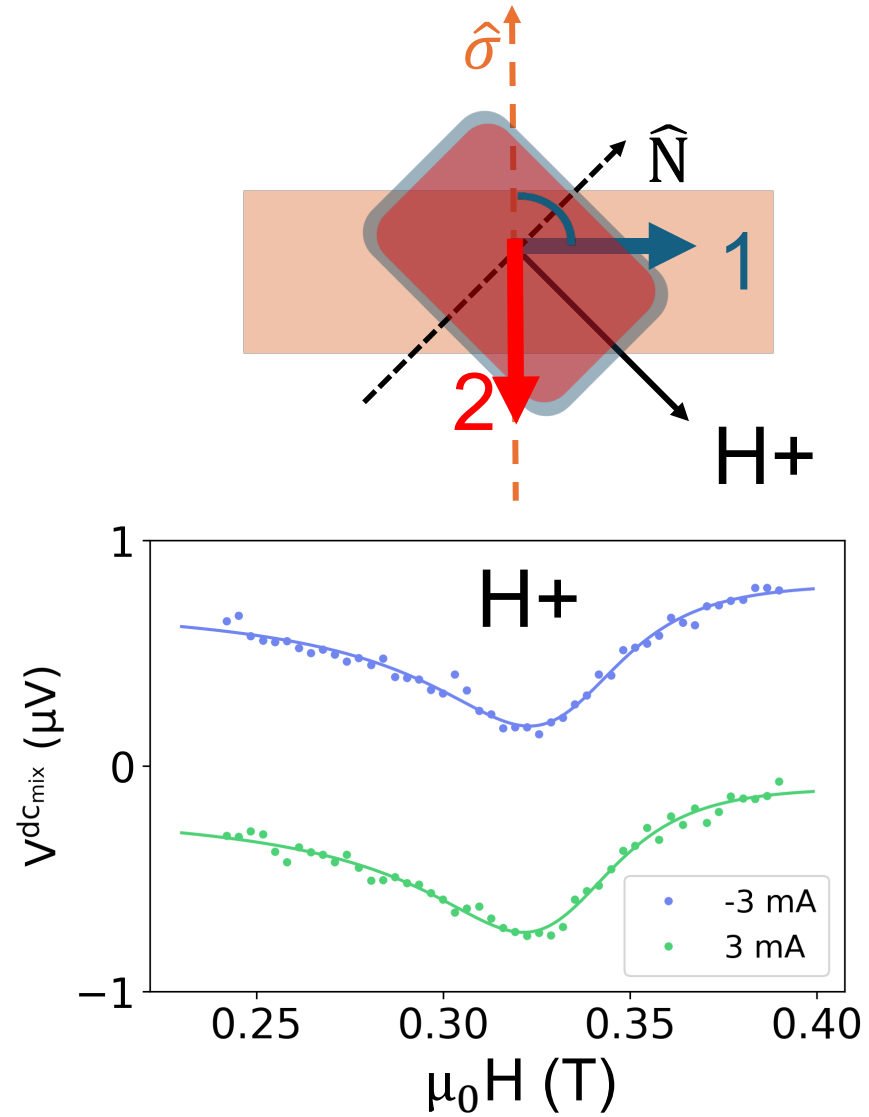
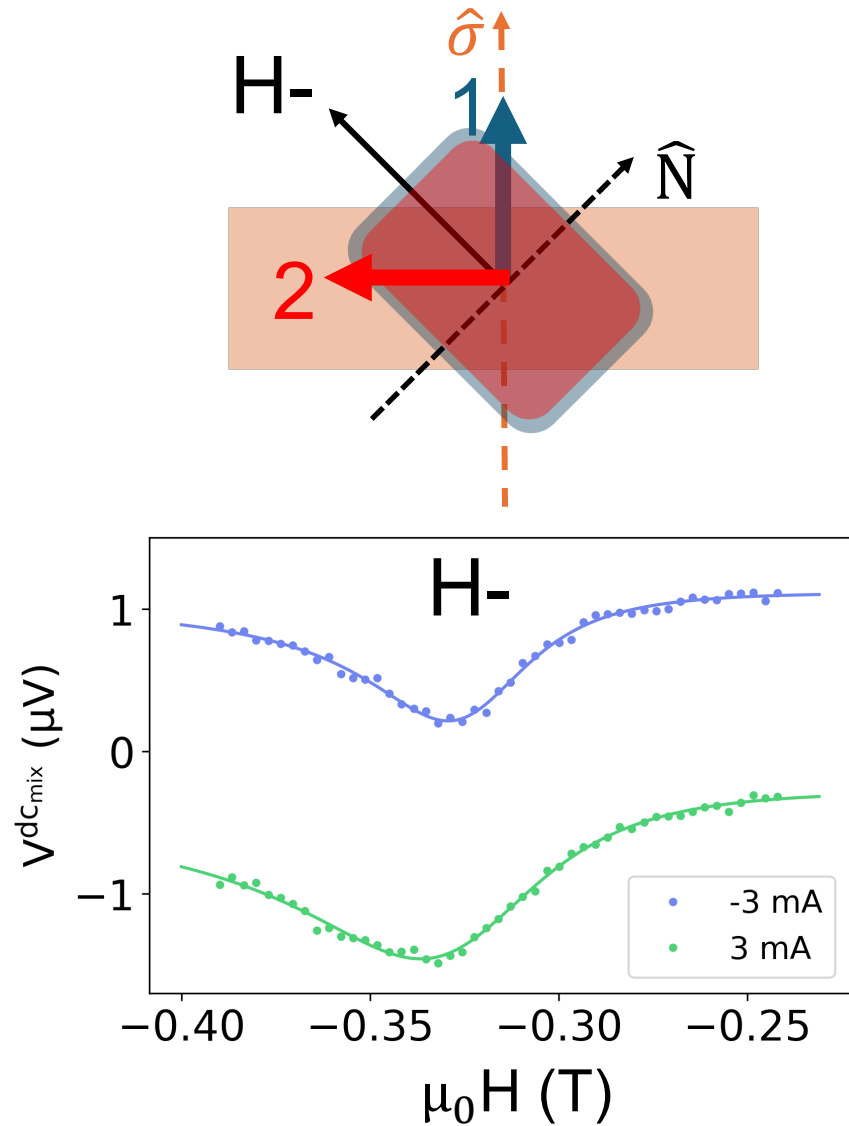
3-Terminal Geometry for AFMR Measurements in a vdW Heterostructure

Xue, L., Wang, C., Cui, Y. T., Liu, L., Swander, A., Sun, J. Z., ... & Ralph, D. (2012). Resonance measurement of nonlocal spin torque in a three-terminal magnetic device. *Physical Review Letters*, 108(14), 147201.



DC current generates spin current through PtTe₂ into CrSBr

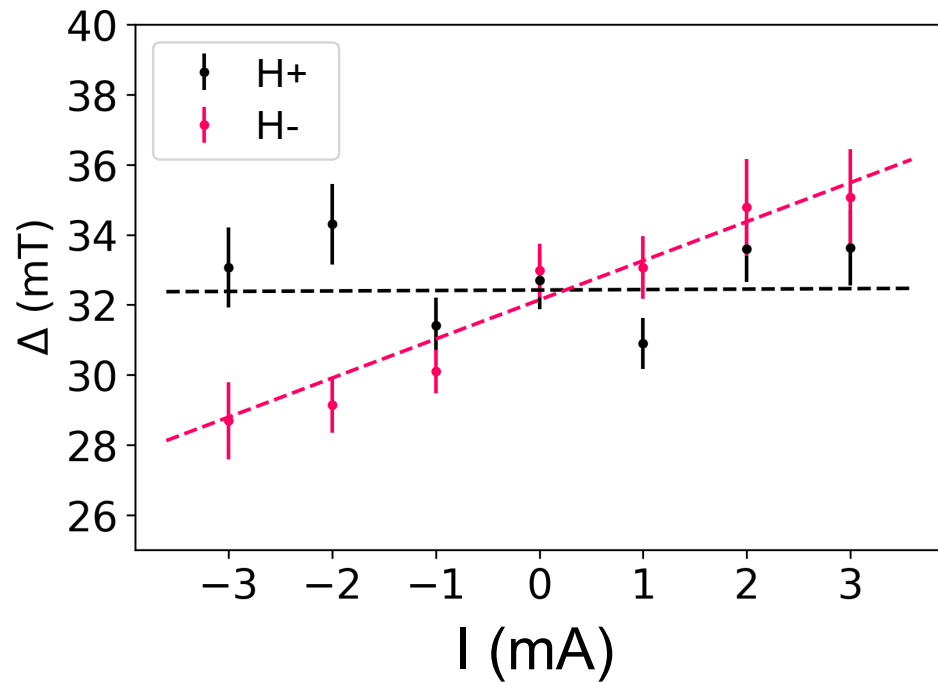
AFMR linewidth modulation



Linewidth is modulated only for the H- configuration.

*arXiv:2407.09462. Science (2025),
DOI: 10.1126/science.adq8590*

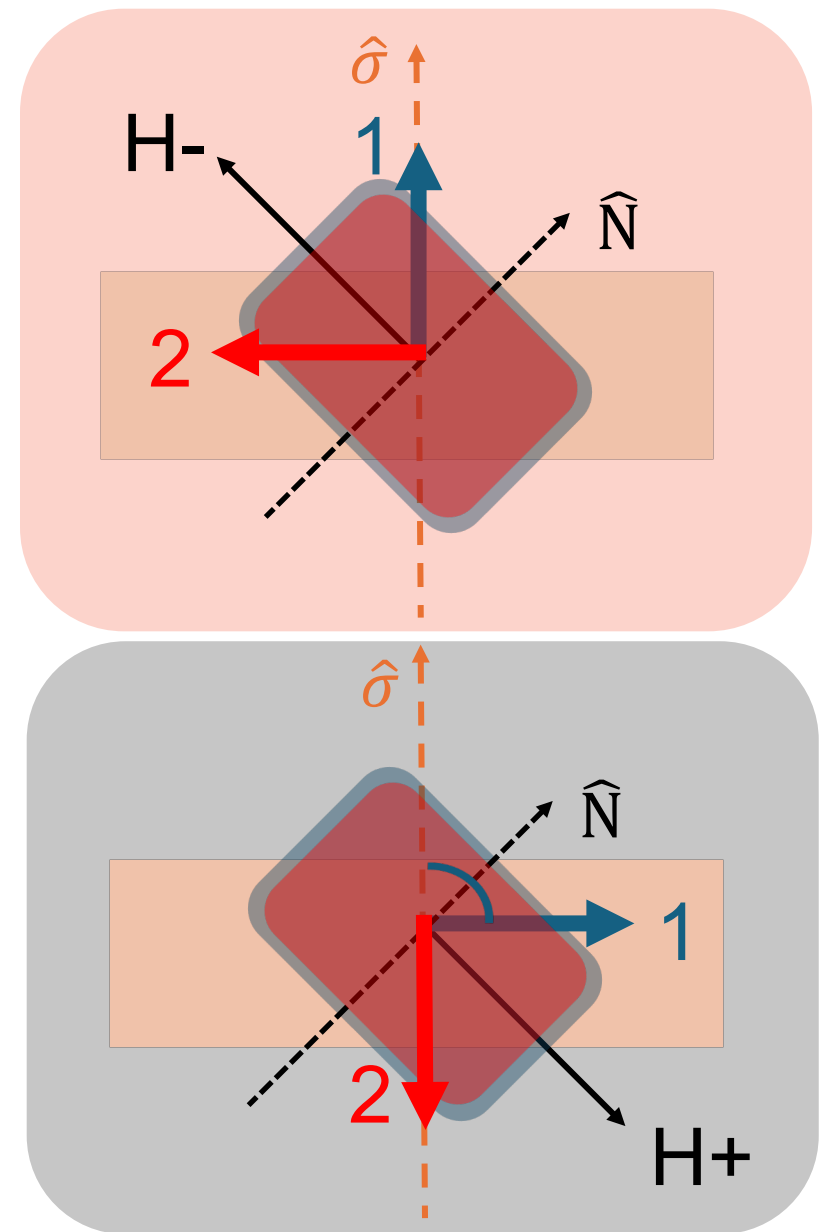
AFMR linewidth modulation



Current induced linewidth modulation slopes are different for H^+ and H^- fields
 → Suggests that **torques are only acting on the interfacial sublattice layer**

$$\frac{d\Delta}{dI} \propto \xi_{SH} \sigma \cdot \hat{m}_1 \quad \longrightarrow \quad \xi_{SH} = 0.29(2)$$

Torque efficiency is comparable with SOT on ferromagnets

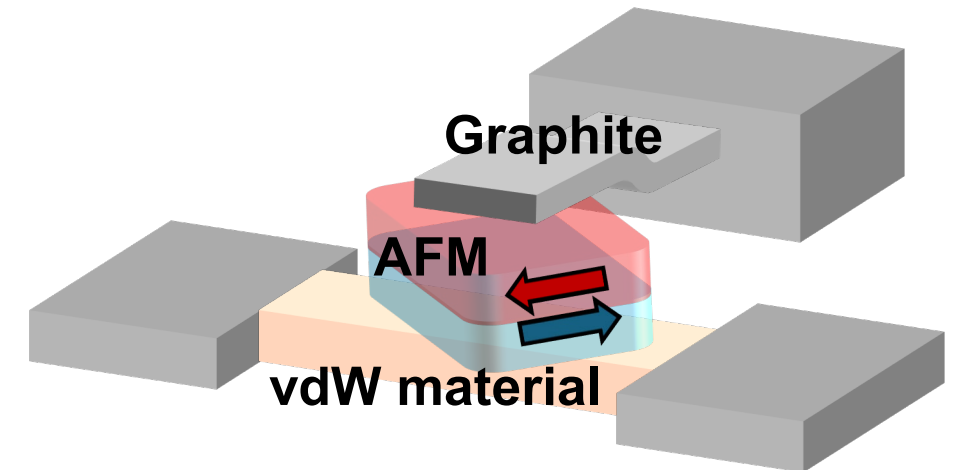
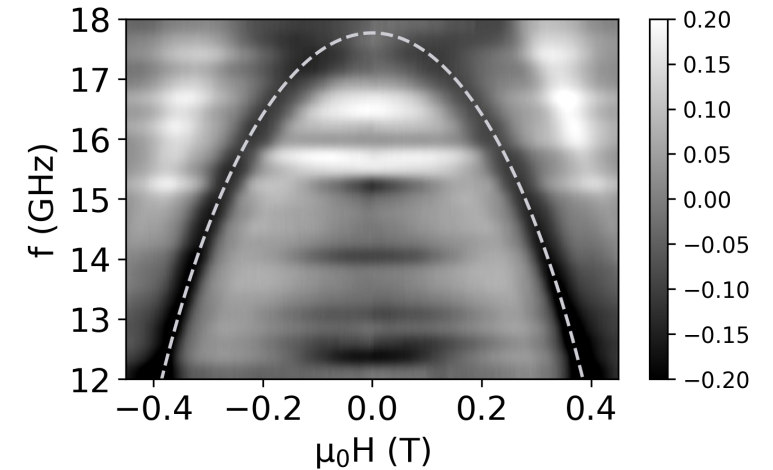


arXiv:2407.09462. Science (2025),
 DOI: 10.1126/science.adq8590.

Summary and Outlook

- Electrical detection of AFMR in bilayer CrSBr.
- SOT acts primarily on interfacial sublattice layer of AFM.
- SOT efficiency on CrSBr is comparable with effect on ferromagnets.

- Future opportunities for investigating AFM dynamics in 2D heterostructures
- Nanoscale GHz-THz AFM oscillators

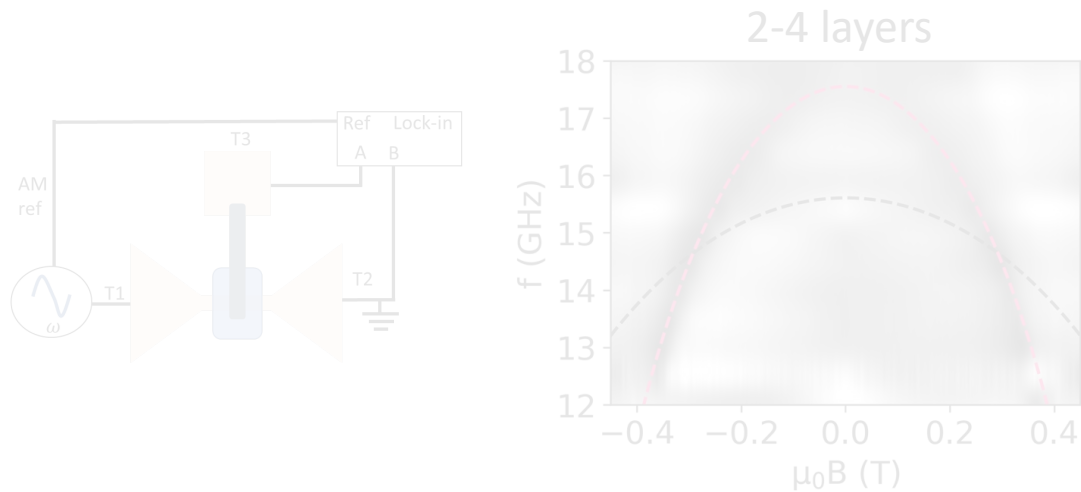


Cham, T. M. J., Huang, X., Chica, D. G., Watanabe, K., Taniguchi, T., Roy, X., Luo, Y. K., & Ralph, D. C.
“Spin-filter tunneling detection of antiferromagnetic resonance with electrically-tunable damping”
arXiv:2407.09462. Science (2025), DOI: 10.1126/science.adq8590

See our related works at: *Nano Letters*, 22(16), 6716-6723 (2022); *Advanced Materials*. 2305739 (2024)

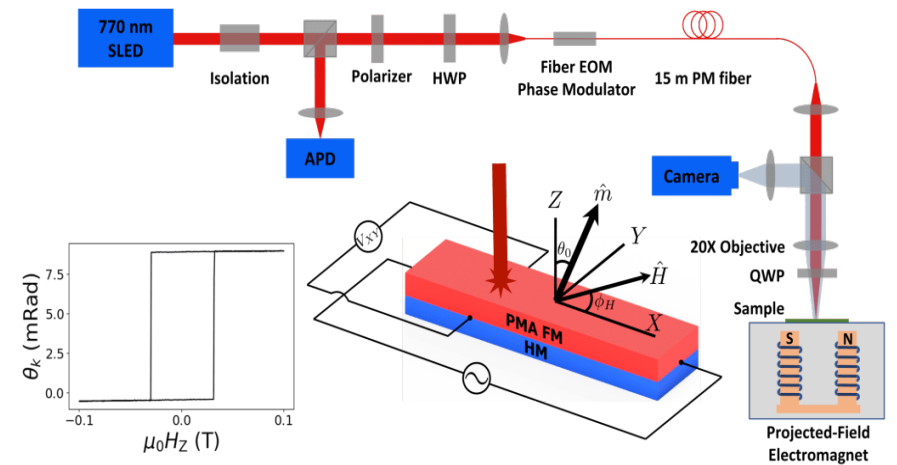
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Electrical detection of antiferromagnetic resonance with electrically-tunable damping



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arXiv: 2407.09462. *Science* (2025), in print

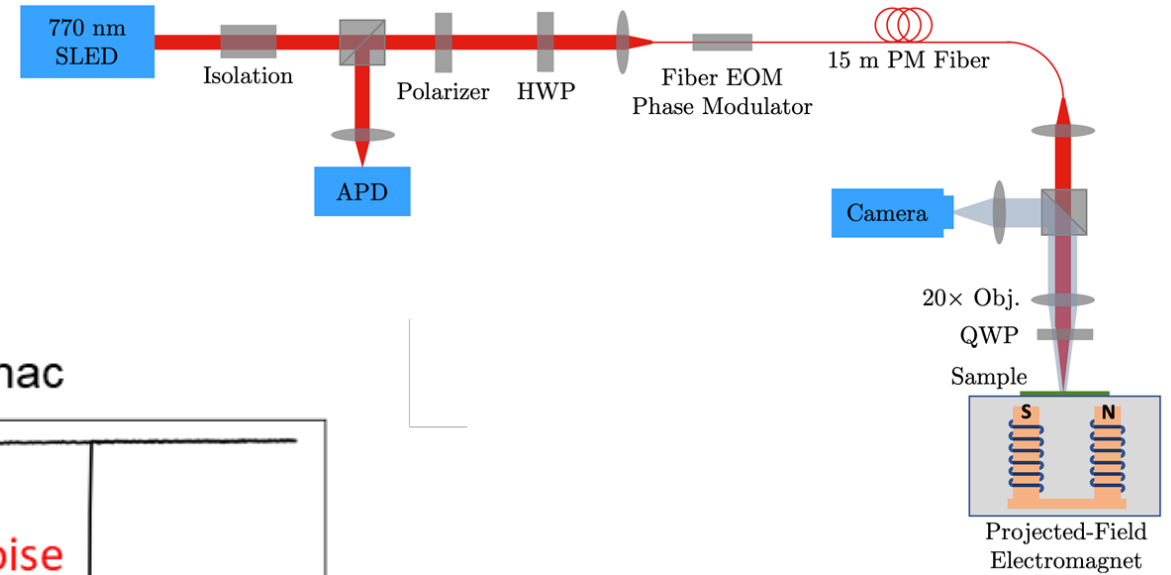
High-sensitivity optical SOT metrology: Sagnac Kerr interferometry



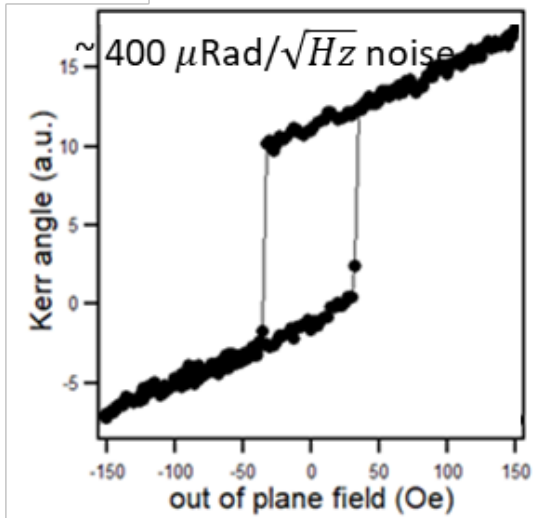
Science Advances 9(36), eadi9039 (2023);
First version: arXiv: 2109.13759 (2021)

High-sensitivity magneto-optic DC readout: Sagnac optical interferometry

At least 50-100x better signal-to-noise than conventional DC MOKE magnetic imaging.

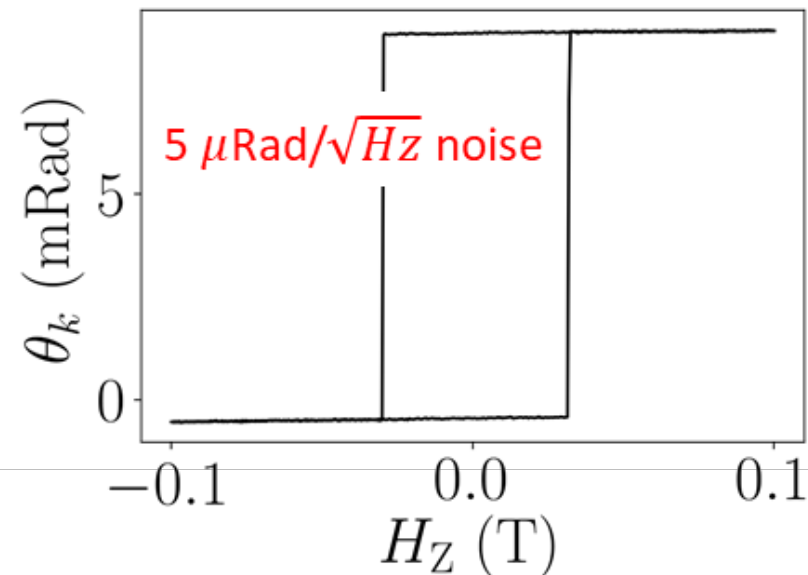


Conventional polar-MOKE signal

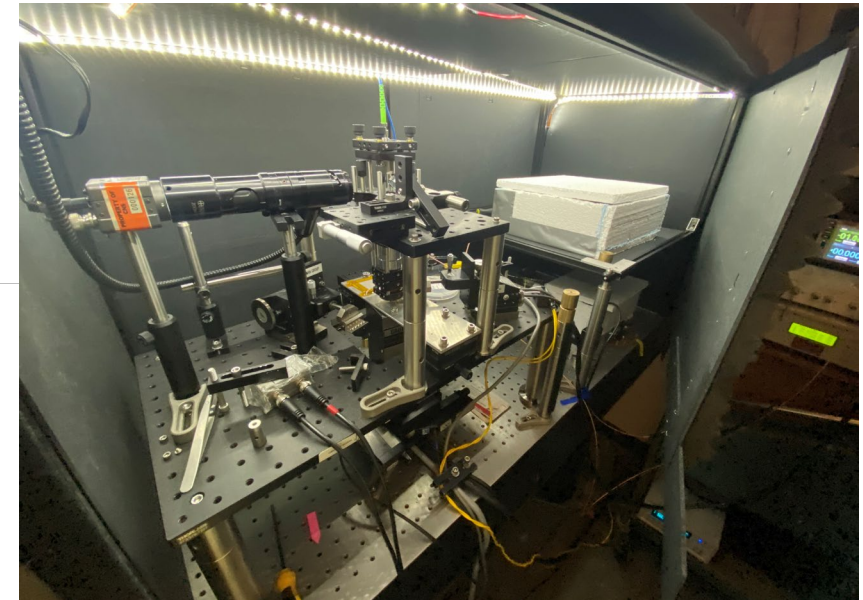
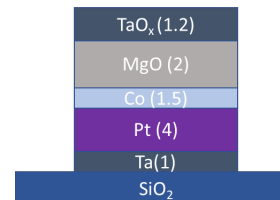


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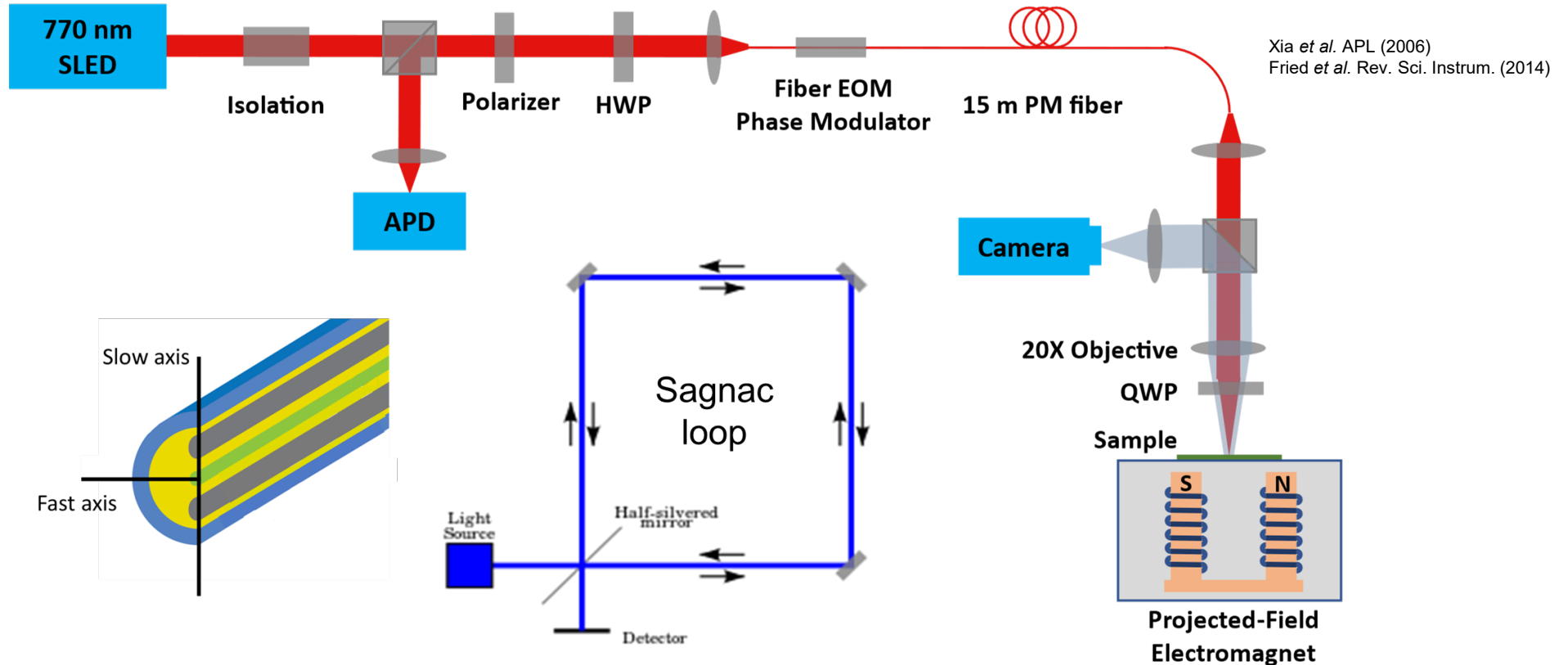
Sagnac



Substrate/Ta(1.5)/Pt(4)/
Co(0.85-1.3)/MgO(1.9)/
Ta(2)



The setup:



- Two spatially overlapped, orthogonally polarized beams travel inside a single-mode polarization-maintaining (PM) fiber along its fast and slow axes.
- Two beams experience different phase modulation depth ($\phi_m = \phi_{fast} - \phi_{slow}$) by an electro-optic phase modulator (EOM) at the modulation frequency w : $\phi_{fast} \sin(wt)$, $\phi_{slow} \sin(wt)$.
- Upon sample reflection, both beams pass the quarter-wave plate (QWP) twice, and travel back along opposite fiber axes to acquire same optical path with a phase difference: $(\phi_{fast} - \phi_{slow})\{\sin[w(t + \tau)] - \sin(wt)\}$, hence forming a Sagnac loop.

Kerr signal detection:

- We tune EOM frequency, w , such that $\tau = \pi/w$, and τ is the time of flight for the 30-meter fiber loop. Sample Kerr rotation can be quantified by 1st and 2nd harmonic interference intensity signals (I^w & I^{2w}):

$$I^w = - \frac{\overset{\text{Kerr rotation}}{\sin 2\theta_k} \overset{\text{Kerr ellipticity}}{J_1(2\phi_m)}}{4r_- r_+}$$

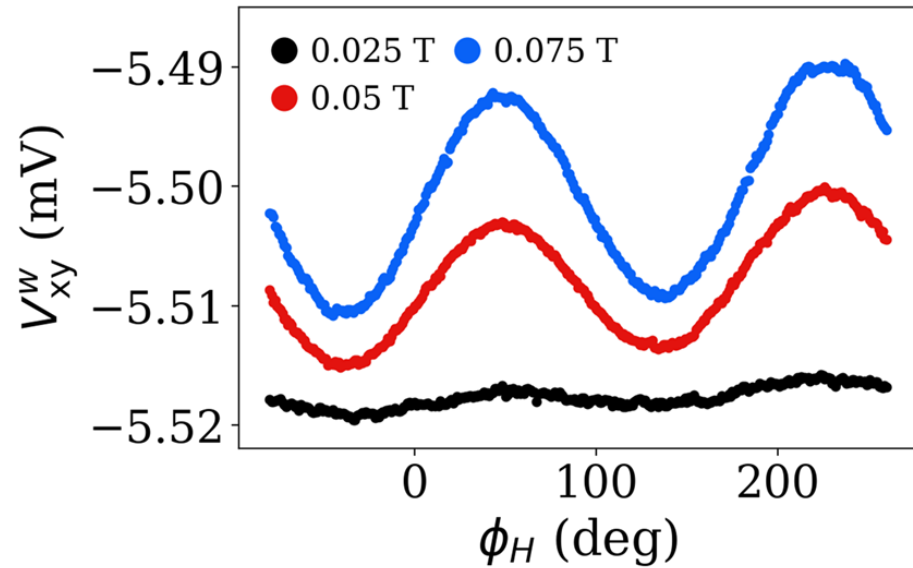
$$I^{2w} = - \frac{\overset{\text{Kerr rotation}}{\cos 2\theta_k} \overset{\text{Kerr ellipticity}}{J_2(2\phi_m)}}{4r_- r_+}$$

$$\theta_k = \frac{1}{2} \tan^{-1} \left[\frac{J_2(2\phi_m) I^w}{J_1(2\phi_m) I^{2w}} \right]$$

J_1, J_2 : Bessel-J functions

Ultrasensitive out-of-plane magnetization: absence of in-plane magnetization detection

Transport Hall voltage ← simultaneously → Sagnac Kerr signal

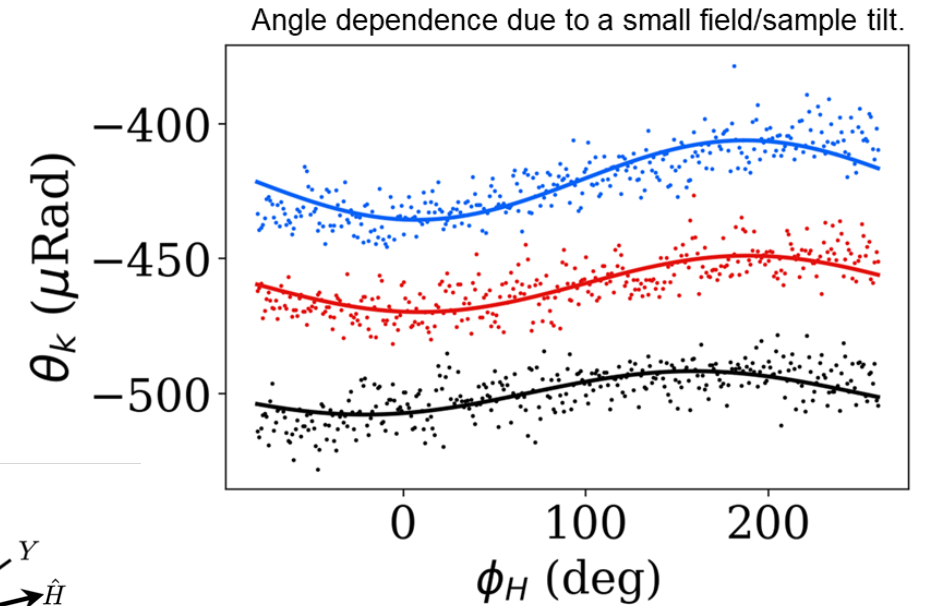
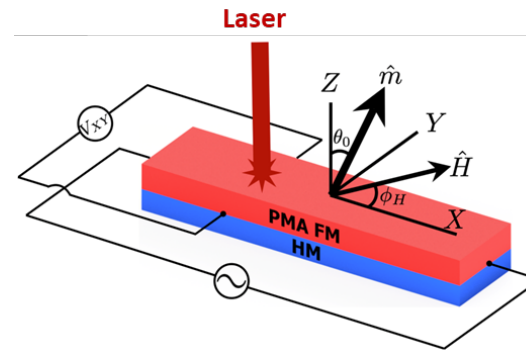


$$V_{XY}^w = \Delta I R_{\text{AHE}} m_z + \boxed{\Delta I R_{\text{PHE}} m_x m_y}$$

↑

Harmonic Hall commonly give inconsistent results due to artifacts associated with planar Hall effect R_{PHE}

See details in our first version: arXiv: 2109.13759 (2021)



$$\theta_k = \kappa m_z + \beta_Q m_x m_y$$

Estimated a factor of 10^{-4} smaller than κm_z

See details in the SI: Science Advances 9(36), eadi9039 (2023)

Using Sagnac interferometry to measure spin-orbit torques

Based on the steady-state Landau-Lifshitz-Gilbert-Slonczewski (LLGS) macrospin equation, we determine the current-induced damping-like and field-like effective torques (per unit magnetization) τ_{DL}^0 and τ_{FL}^0 by balancing the following equation:

$$\gamma\mu_0\Delta\hat{m} \times \vec{H}_{\text{eff}} = \tau_{DL}^0\hat{m} \times (\hat{\sigma} \times \hat{m}) + \tau_{FL}^0\hat{\sigma} \times \hat{m}$$

Samples with perpendicular magnetic anisotropy

$$\theta_k = \pm\kappa \left(1 - \frac{H^2}{2M_{\text{eff}}^2}\right)$$

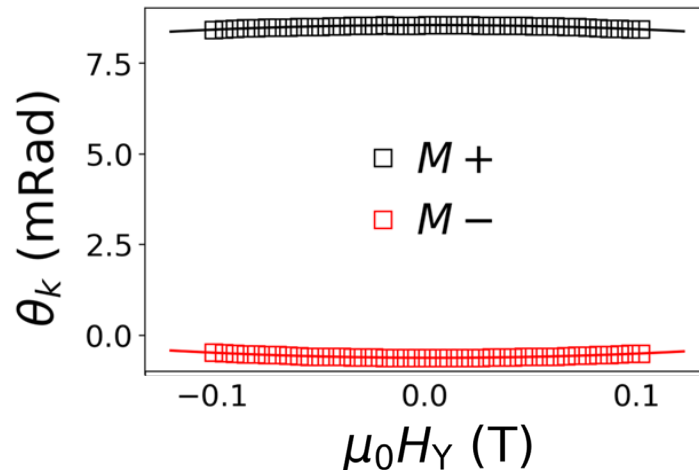
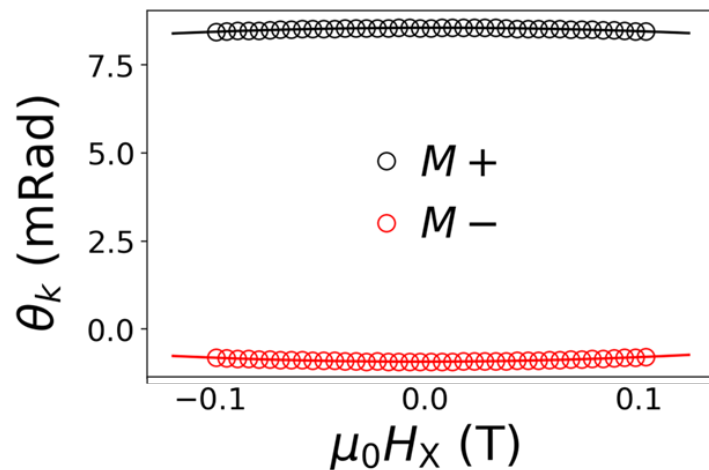
- Sagnac Kerr rotation θ_k sensitively measures changes in the OOP magnetization m_z that are **second order in small-angle tilting from the OOP direction**.

Samples with in-plane magnetic anisotropy

$$\Delta\theta_k = \frac{\kappa\Delta H_{DL} \cos \phi_H}{H - M_{\text{eff}}}$$

- The current-induced changes in m_z are **first order in the OOP tilting angle**.

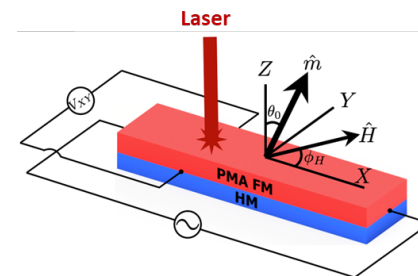
Tilting from applied external magnetic fields



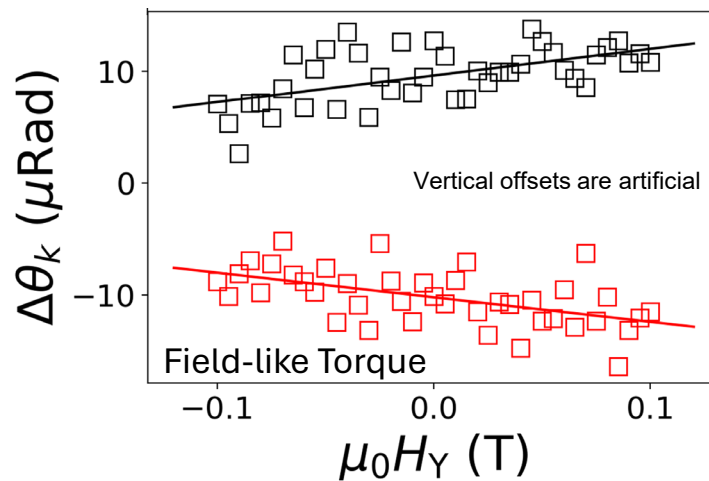
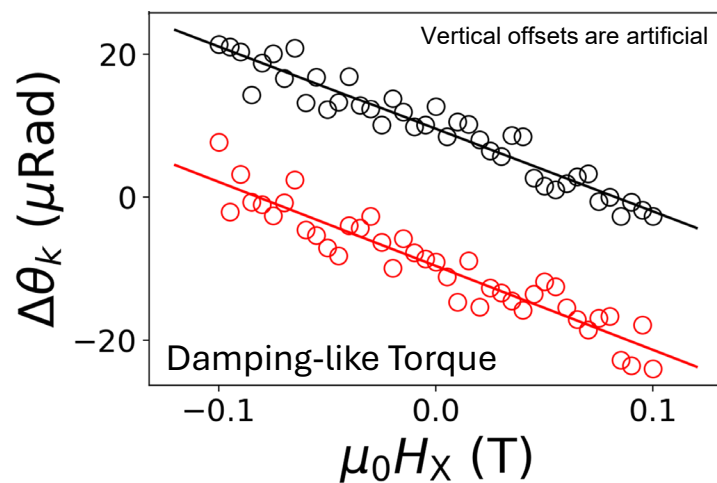
Samples with perpendicular magnetic anisotropy

$$\theta_k \approx \pm \kappa \left(1 - \frac{H_{X(Y)}^2}{2\mu_0^2 M_{\text{eff}}^2} \right)$$

κ : a coupling constant between m_z and θ_k , analogous to R_{AHE} .



Tilting from current induced M_z motion

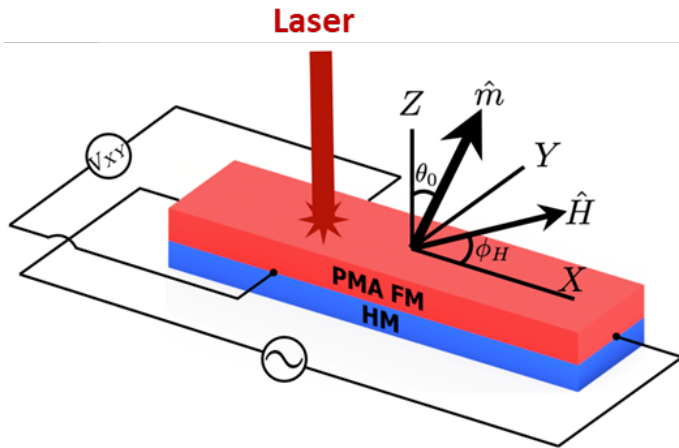
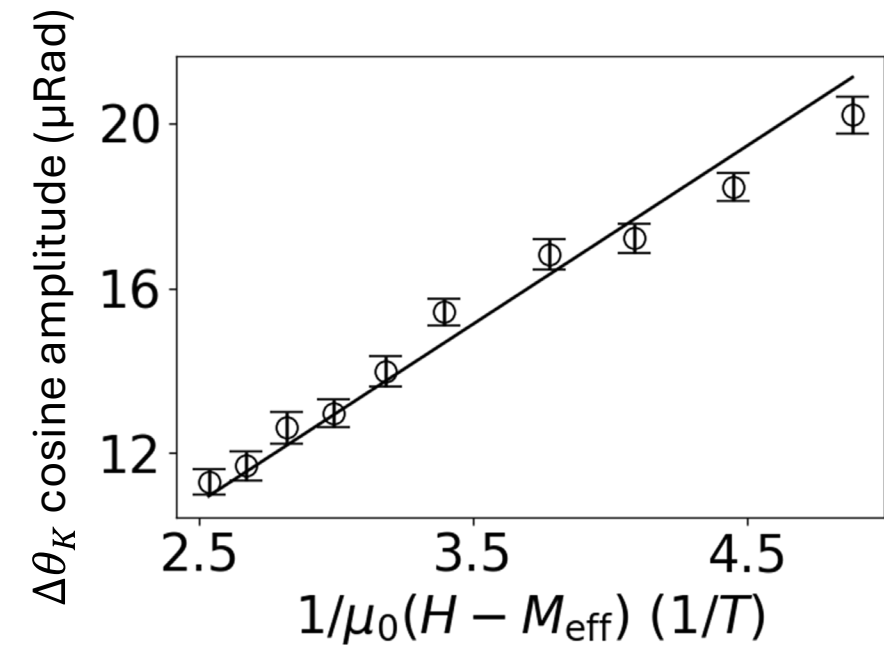
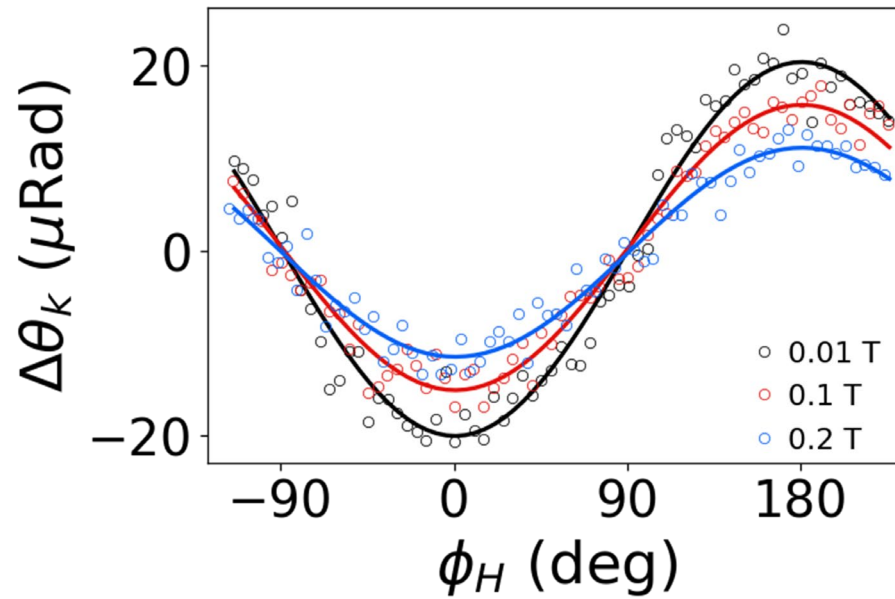


Slope measures the spin-torque effective magnetic field $\Delta H_{X(Y)}$

Current-induced Kerr signal:

$$\Delta\theta_k \approx \pm \kappa \Delta H_{X(Y)} \frac{H_{X(Y)}}{\mu_0^2 M_{\text{eff}}^2}$$

$$\begin{aligned} \mu_0 \Delta H_X &= \mp \tau_{\text{DL}}^0 / \gamma \\ \mu_0 \Delta H_Y &= \mu_0 H_{\text{Oe}} + \tau_{\text{FL}}^0 / \gamma \end{aligned}$$

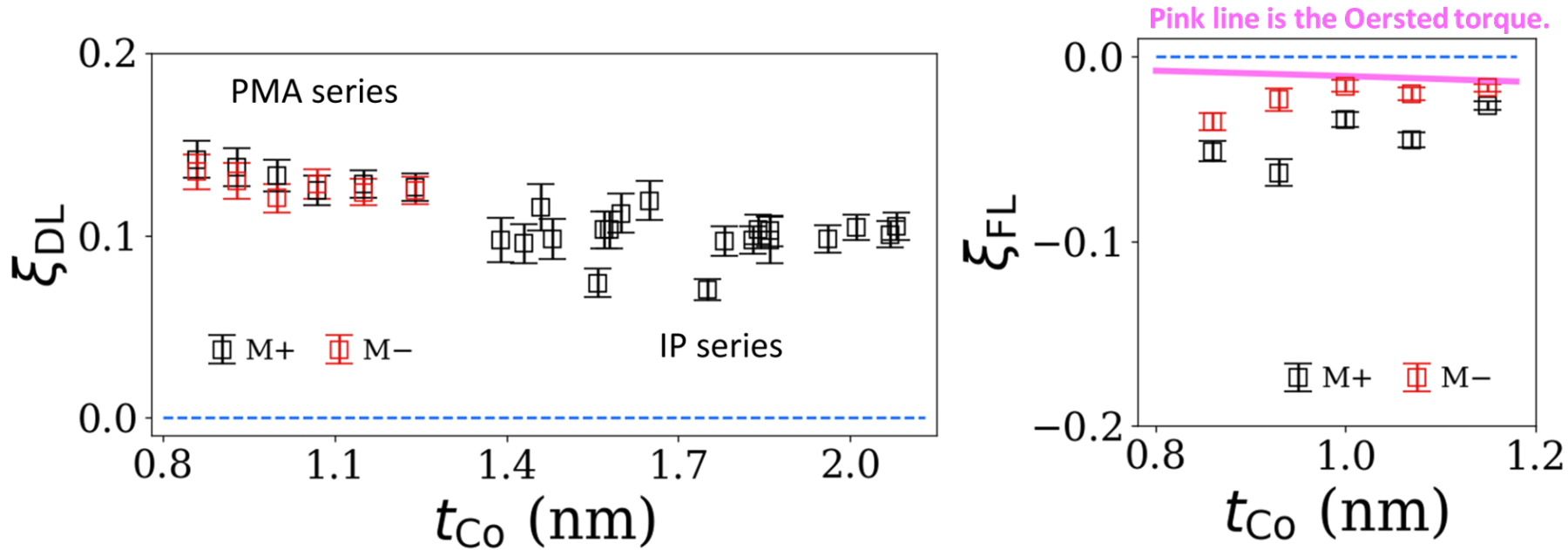


Samples with in-plane magnetic anisotropy

$$\Delta\theta_k = \frac{\kappa \Delta H_{\text{DL}} \cos \phi_H}{H - M_{\text{eff}}}$$

- The current-induced changes in m_Z are **first order in the OOP tilting angle**.
- Damping-like torque (τ_{DL}^0) corresponds to an OOP effective field, while the field-like torque (τ_{FL}^0) gives an in-plane effective field.

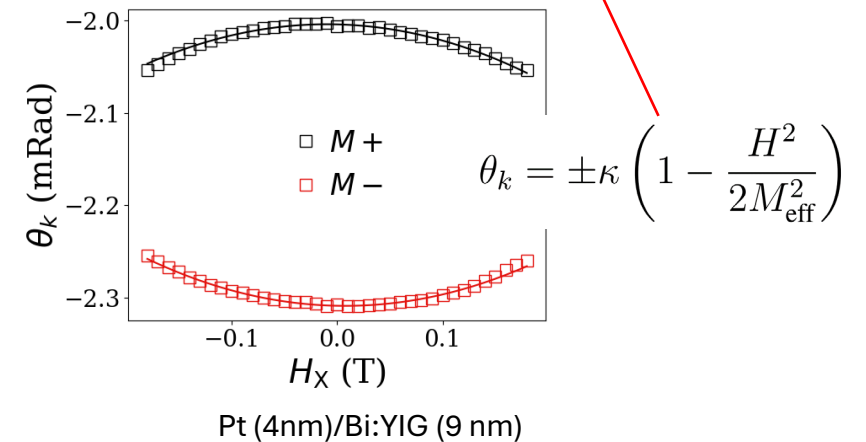
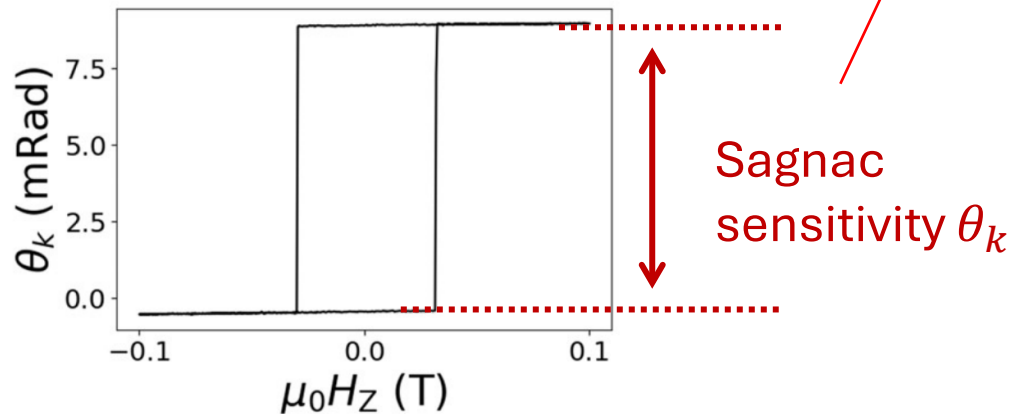
Results for the damping-like (ξ_{DL}) and field-like (ξ_{FL}) spin-orbit-torque efficiencies for the sample series substrate/Ta(1.5)/Pt(4)/Co(0.85–2.1)/MgO(1.9)/Ta(2)



- Co thickness variation gives competition between in-plane shape anisotropy and interfacial perpendicular magnetic anisotropy (PMA), resulting in different values of effective magnetization M_{eff} .
- Sagnac results for damping-like torque efficiency ξ_{DL} on PMA and in-plane samples are consistent, which is often not the case for electrically-based measurements.

Sagnac Kerr sensitivity for metallic v.s. insulating 3D magnets

Samples	Anisotropy	θ_k (mRad) as-grown	θ_k (mRad) after Pt sputtering	$\mu_0 M_{eff}$ (T) as-grown	$\mu_0 M_{eff}$ (T) after Pt sputtering
Ferromagnet metal: Pt (4 nm)/Co (1.4 nm)	Weakly PMA	N/A	8 (4nm Pt)	N/A	0.12 (4nm Pt)
Ferrimagnet insulator: Bi:YIG (9 nm) on GSGG substrate	PMA	0.54	0.25 (4nm Pt)	0.32	0.16 (4 nm Pt)
Ferromagnet insulator: LAFO (8.5 nm) on MgGa ₂ O ₄ substrate	PMA	0.057	0.025 (2 nm Pt)	0.25	0.21 (2 nm Pt)



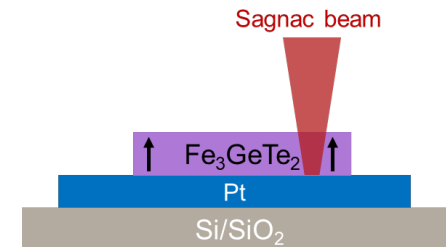
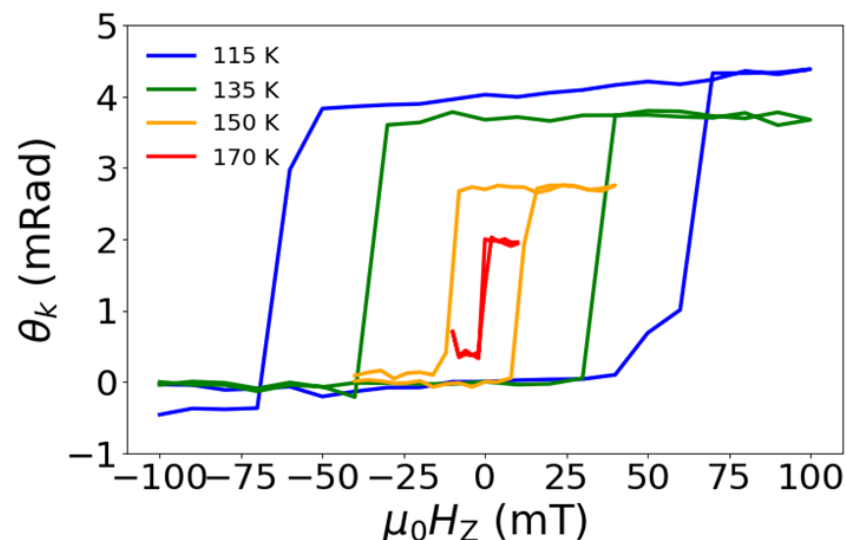
Cryo-Sagnac: towards high-efficiency SOT switching with 2D magnets

2D magnets: potential for ultralow current switching due to reduced net magnetization.

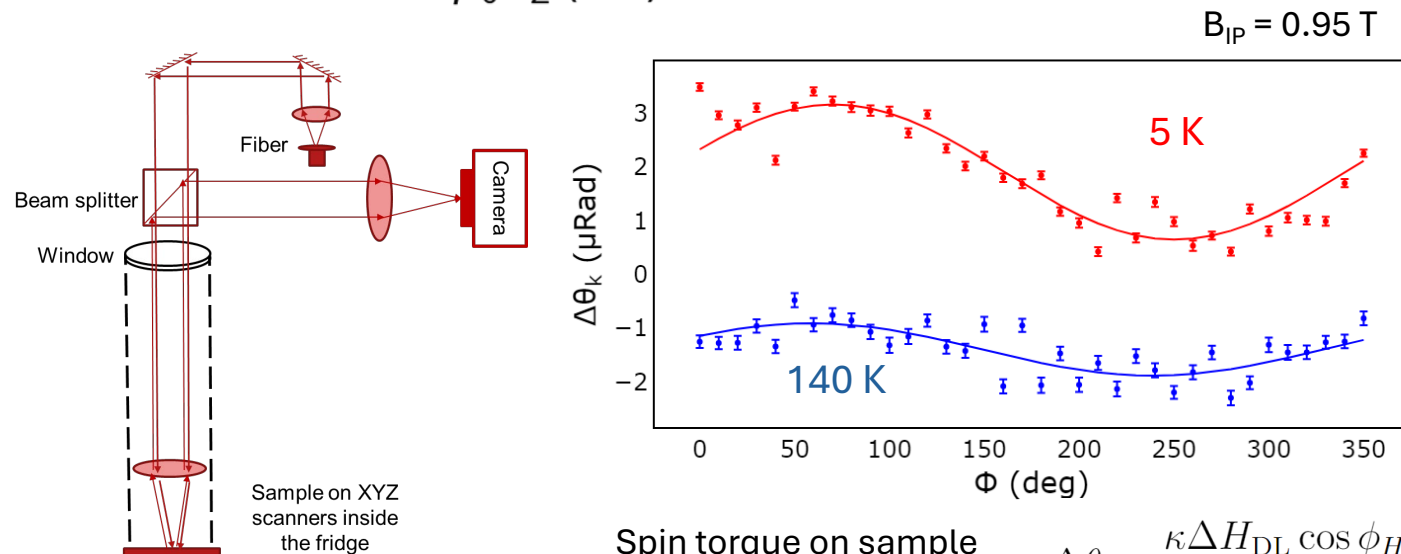
Cryo-Sagnac: outstanding probe especially for **insulating 2D magnets** due to challenging electrical readout.



- Variable sample temp: 1.7 – 320 K
- 9-1-1 T vector superconducting magnets



Fe_3GeTe_2 single crystal grown by Andrew May (Oakridge)



Spin torque on sample with in-plane anisotropy

$$\Delta\theta_k = \frac{\kappa \Delta H_{DL} \cos \phi_H}{H - M_{eff}}$$

Outstanding opportunities in multifunctional vdW heterostructures for spin-based quantum information processing

**Next-gen spin-orbit torque
MRAM devices based on
altermagnetic and topological
materials**



**Ultrafast spin, valley and magnon
dynamics revealed by time-resolved
Sagnac Kerr interferometry, tr-XMCD,
and tr-ARPES**

**Air-free integration of vdW and non-
vdW materials through collaborative
thin film and bulk crystal growths**

**Superconducting spin torque for
cryogenic memory**

Ultrafast Quantum Opto-Spintronics Lab:
<https://sites.usc.edu/kellyluolab/>